

RX64M Group, RX71M Group Flash Memory

User's Manual: Hardware Interface

RENESAS 32-Bit MCU
RX Family / RX600 Series, RX700 Series

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General Precautions in the Handling of MPU/MCU Products

The following usage notes are applicable to all MPU/MCU products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Handling of Unused Pins

Handle unused pins in accordance with the directions given under Handling of Unused Pins in the manual.

- The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible. Unused pins should be handled as described under Handling of Unused Pins in the manual.

2. Processing at Power-on

The state of the product is undefined at the moment when power is supplied.

- The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the moment when power is supplied.
In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the moment when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the moment when power is supplied until the power reaches the level at which resetting has been specified.

3. Prohibition of Access to Reserved Addresses

Access to reserved addresses is prohibited.

- The reserved addresses are provided for the possible future expansion of functions. Do not access these addresses; the correct operation of LSI is not guaranteed if they are accessed.

4. Clock Signals

After applying a reset, only release the reset line after the operating clock signal has become stable. When switching the clock signal during program execution, wait until the target clock signal has stabilized.

- When the clock signal is generated with an external resonator (or from an external oscillator) during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Moreover, when switching to a clock signal produced with an external resonator (or by an external oscillator) while program execution is in progress, wait until the target clock signal is stable.

5. Differences between Products

Before changing from one product to another, i.e. to a product with a different part number, confirm that the change will not lead to problems.

- The characteristics of an MPU or MCU in the same group but having a different part number may differ in terms of the internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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1. Features

The features of the flash memory are described below. See the User's Manual: Hardware for information on the capacity, block configuration, and addresses of the flash memory in this MCU.

Programming/Erase

A dedicated sequencer for the flash memory (flash sequencer) executes programming and erasure via internal peripheral bus 6. The flash sequencer also supports the suspension or resumption of programming or erasure, and background operations (BGO).

Security Functions

The flash memory incorporates hardware functions to prevent illicit tampering with or reading out of data in flash memory.

Protection Functions

The flash memory incorporates hardware functions to prevent erroneous programming.

Interrupts

The flash memory supports an interrupt to indicate completion of processing by the flash sequencer and an error interrupt to indicate operations that were in error.

2. Module Configuration

Modules related to the flash memory are configured as shown in Figure 2.1. The flash sequencer is configured of the Flash Control Unit (FCU) and Flash Application Command Interface (FACI). The FCU executes basic control of overwriting of the flash memory. The FCURAM is RAM for the storage of firmware to control execution by the FCU. The FACI receives FACI commands via internal peripheral bus 6 and controls FCU operations accordingly.

In response to a reset, the FACI transfers data from the flash memory to the option-setting memory.

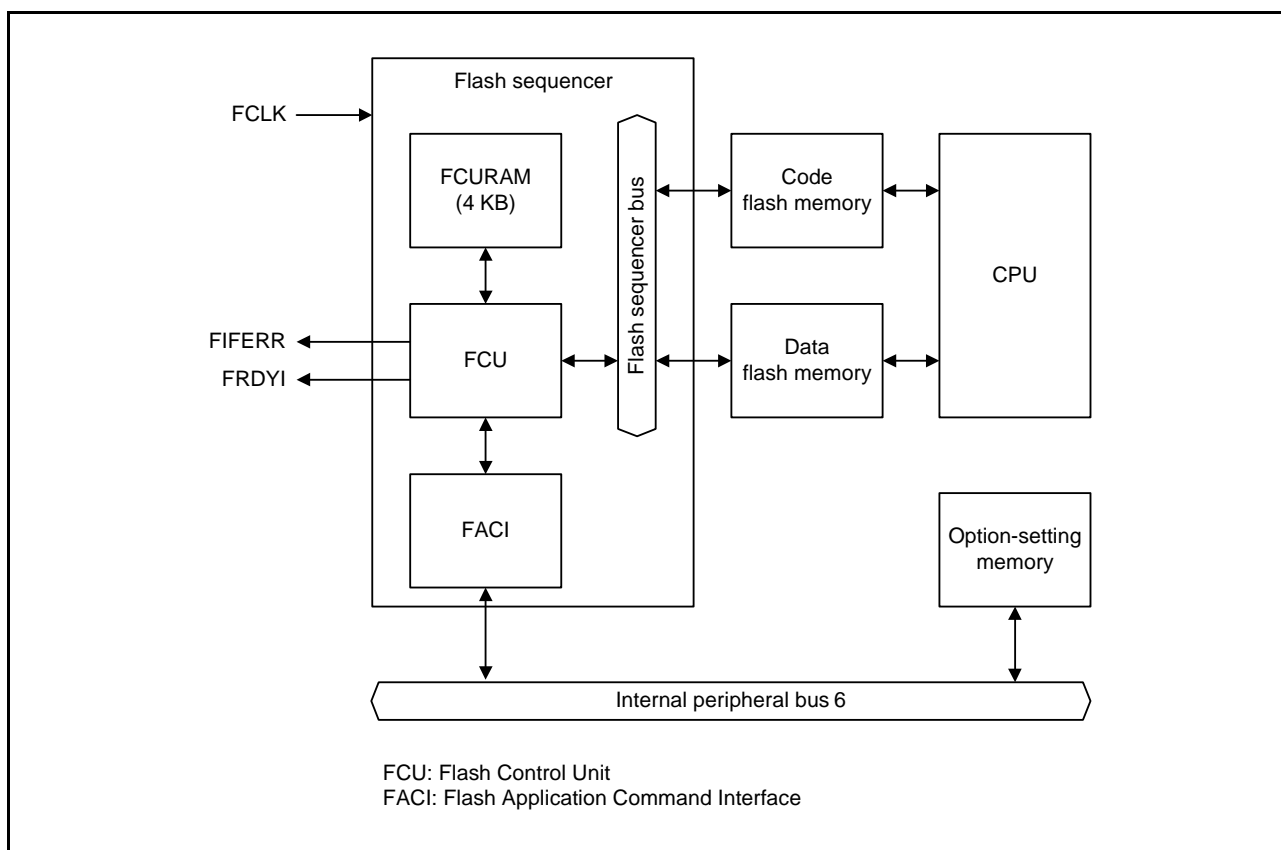


Figure 2.1 Configuration of Flash Memory Related Modules

3. Address Space

Using the hardware interface with the flash memory requires accessing to the area containing registers of the hardware, that for the issuing of FACI commands, that for storage of the FCU firmware, and that for the FCURAM. Table 3.1 gives information on all of these areas.

Table 3.1 Information on the Hardware Interface Area

Area	Address	Capacity
Area containing the various registers of the hardware	See section 4, Registers.	See section 4, Registers.
FACI command-issuing area	007E 0000h	4 bytes
FCU firmware storage area	FEFF F000h to FEFF FFFFh	4 Kbytes
FCURAM area	007F 8000h to 007F 8FFFh	4 Kbytes
Configuration setting area	0012 0040h to 0012 007Fh	64 bytes

Refer to the User's Manual: Hardware for information on the addresses of the flash memory.

4. Registers

This section gives information on registers to which access is required when using the hardware interface of the flash memory. Reset registers that are not specifically mentioned to their initial states.

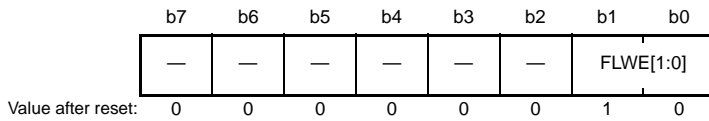
For information on the option-setting memory, see the User's Manual: Hardware for the product you are using.

Table 4.1 List of Registers

Address	Module Symbol	Register Name	Register Symbol	Number of Bits	Access Size	Number of Access Cycles		Reference Page
						ICLK \geq PCLKB/FCLK	ICLK $<$ PCLKB/FCLK	
0008 C296h	FLASH	Flash P/E Protect Register	FWEPROR	8	8	4 to 5 PCLKB	2 to 3 ICLK	10
007F E010h	FLASH	Flash Access Status Register	FASTAT	8	8	2 to 4 FCLK	2 to 3 ICLK	11
007F E014h	FLASH	Flash Access Error Interrupt Enable Register	FAEINT	8	8	2 to 4 FCLK	2 to 3 ICLK	13
007F E018h	FLASH	Flash Ready Interrupt Enable Register	FRDYIE	8	8	2 to 4 FCLK	2 to 3 ICLK	14
007F E030h	FLASH	FACI Command Start Address Register	FSADDR	32	32	2 to 4 FCLK	2 to 3 ICLK	15
007F E034h	FLASH	FACI Command End Address Register	FEADDR	32	32	2 to 4 FCLK	2 to 3 ICLK	16
007F E054h	FLASH	FCURAM Enable Register	FCURAME	16	16	2 to 4 FCLK	2 to 3 ICLK	17
007F E080h	FLASH	Flash Status Register	FSTATR	32	32	2 to 4 FCLK	2 to 3 ICLK	18
007F E084h	FLASH	Flash P/E Mode Entry Register	FENTRYR	16	16	2 to 4 FCLK	2 to 3 ICLK	22
007F E088h	FLASH	Flash Protection Register	FPROTR	16	16	2 to 4 FCLK	2 to 3 ICLK	23
007F E08Ch	FLASH	Flash Sequencer Set-Up Initialization Register	FSUINTR	16	16	2 to 4 FCLK	2 to 3 ICLK	24
007F E090h	FLASH	Lock Bit Status Register	FLKSTAT	8	8	2 to 4 FCLK	2 to 3 ICLK	25
007F E0A0h	FLASH	FACI Command Register	FCMDR	16	16	2 to 4 FCLK	2 to 3 ICLK	26
007F E0C0h	FLASH	Flash P/E Status Register	FPESTAT	16	16	2 to 4 FCLK	2 to 3 ICLK	27
007F E0D0h	FLASH	Data Flash Blank Check Control Register	FBCCNT	8	8	2 to 4 FCLK	2 to 3 ICLK	27
007F E0D4h	FLASH	Data Flash Blank Check Status Register	FBCSTAT	8	8	2 to 4 FCLK	2 to 3 ICLK	28
007F E0D8h	FLASH	Data Flash Programming Start Address Register	FPSADDR	32	32	2 to 4 FCLK	2 to 3 ICLK	28
007F E0E0h	FLASH	Flash Sequencer Processing Switching Register	FCPSR	16	16	2 to 4 FCLK	2 to 3 ICLK	29
007F E0E4h	FLASH	Flash Sequencer Processing Clock Notification Register	FPCKAR	16	16	2 to 4 FCLK	2 to 3 ICLK	30

4.1 Flash P/E Protect Register (FWEPROR)

Address(es): 0008 C296h



Bit	Symbol	Bit Name	Description	R/W															
b1, b0	FLWE[1:0]	Flash Programming and Erasure	<table border="0"> <tr> <td style="padding-right: 10px;">b1</td> <td>b0</td> <td></td> </tr> <tr> <td>0</td> <td>0</td> <td>0: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.</td> </tr> <tr> <td>0</td> <td>1</td> <td>1: Permits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.</td> </tr> <tr> <td>1</td> <td>0</td> <td>0: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.</td> </tr> <tr> <td>1</td> <td>1</td> <td>1: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.</td> </tr> </table>	b1	b0		0	0	0: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.	0	1	1: Permits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.	1	0	0: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.	1	1	1: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.	R/W
b1	b0																		
0	0	0: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.																	
0	1	1: Permits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.																	
1	0	0: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.																	
1	1	1: Prohibits programming and erasure of the code flash, data flash, or option-setting memory, programming and erasure of lock bits, and blank checking.																	
b7 to b2	—	Reserved	These bits are read as 0. The write value should be 0.	R/W															

Programming and erasure of the code flash memory, data flash memory, or option-setting memory, programming and erasure of lock bits, and blank checking are prohibited by hardware.

FWEPROR is initialized by a reset due to the signal on the RES# pin, a power-on reset, a voltage-monitoring 0 reset, an independent watchdog timer reset, a watchdog timer reset, a voltage-monitoring 1 reset, a voltage-monitoring 2 reset, and a software reset, and by transitions to software standby and deep software standby.

4.2 Flash Access Status Register (FASTAT)

Address(es): 007F E010h

b7	b6	b5	b4	b3	b2	b1	b0
CFAE	—	—	CMDLK	DFAE	—	—	ECRCT
Value after reset:	0	0	0	0	0	0	0

Bit	Symbol	Bit Name	Description	R/W
b0	ECRCT	Error Flag	0: No error has occurred. 1: An error has occurred.	R
b2, b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b3	DFAE	Data Flash Memory Access Violation Flag	0: No data flash memory access violation has occurred. 1: A data flash memory access violation has occurred.	R/W*1
b4	CMDLK	Command Lock Flag	0: The flash sequencer is not in the command-locked state. 1: The flash sequencer is in the command-locked state.	R
b6, b5	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b7	CFAE	Code Flash Memory Access Violation Flag	0: No code flash memory access violation has occurred. 1: A code flash memory access violation has occurred.	R/W*1

Note 1. Only 0 can be written to clear the flag after 1 is read.

FASTAT register indicates whether a code flash memory or data flash memory access violation has occurred. If any of the CFAE, CMDLK and DFAE flags is set to 1, the flash sequencer enters the command-locked state (see section 7.2, Error Protection). To release it from the command-locked state, a status clear command or forced stop command must be issued by the FACI after clearing the CFAE and DFAE flags in the FASTAT register to 0.

ECRCT Flag (Error Flag)

This flag indicates that a 1-bit error has been corrected in reading of the flash memory area by the flash sequencer (with parameters for configuration setting or programming) or reading of the FCURAM.

When a 2-bit error is detected in reading of the FCURAM, CMDLK is set to 1 (the flash sequencer is in the command-locked state) and the ECRCT flag does not change.

[Setting Conditions]

- When the flash sequencer reads the flash memory area (configuration setting and programming parameters).
- When a 1-bit error is corrected by reading the FCURAM.

[Clearing Condition]

- When the flash sequencer starts processing of a forced stop command while the FRCRCT flag in the FSTATR register is 1.

DFAE Flag (Data Flash Memory Access Violation Flag)

This flag indicates whether a data flash memory access violation occurred. If this flag is set to 1, the FSTATR.ILGLERR flag is set to 1, placing the flash sequencer in the command-locked state.

[Setting Conditions]

In general, commands being issued in data flash memory P/E mode as described below.

- An FACI command being issued while the setting of b18 to b0 in the FSADDR register is 1 0000h to 7 FFFFh (indicating the reserved portion of the data area)
- A configuration setting command being issued while the setting of b18 to b0 in the FSADDR register is 0 0000h to 0 003Fh or 0 0100h to 7 FFFFh.

[Clearing Condition]

- 0 being written after reading of 1.

CMDLK Flag (Command Lock Flag)

This flag indicates that the flash sequencer is in the command-locked state.

[Setting Condition]

- The flash sequencer detects an error and enters the command-locked state.

[Clearing Condition]

- The flash sequencer starting to process a status clear or forced stop command while the CFAE or DFAE flag in the FASTAT register is 0.

CFAE Flag (Code Flash Memory Access Violation Flag)

This flag indicates whether a code flash memory access violation has occurred. If this flag is set to 1, the FSTATR.ILGLERR flag is set to 1, placing the flash sequencer in the command-locked state.

[Setting Conditions]

An FACI command being issued in code flash memory P/E mode while settings are as follows:

- The setting of b23 to b0 in the FSADDR register is 00 0000h to BF FFFFh (reserved portion of the user area).

[Clearing Condition]

- 0 being written after reading of 1.

4.3 Flash Access Error Interrupt Enable Register (FAEINT)

Address(es): 007F E014h

	b7	b6	b5	b4	b3	b2	b1	b0
	CFAEIE	—	—	CMDLKIE	DFAEIE	—	—	ECRCTIE
Value after reset:	1	0	0	1	1	0	0	1

Bit	Symbol	Bit Name	Description	R/W
b0	ECRCTIE	Error Interrupt Enable	0: Generation of an FIFERR interrupt request is disabled when FASTAT.ECRCT is set to 1. 1: Generation of an FIFERR interrupt request is enabled when FASTAT.ECRCT is set to 1.	R/W
b2, b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b3	DFAEIE	Data Flash Memory Access Violation Interrupt Enable	0: Generation of an FIFERR interrupt request is disabled when FASTAT.DFAE is set to 1. 1: Generation of an FIFERR interrupt request is enabled when FASTAT.DFAE is set to 1.	R/W
b4	CMDLKIE	Command Lock Interrupt Enable	0: Generation of an FIFERR interrupt request is disabled when FASTAT.CMDLK is set to 1. 1: Generation of an FIFERR interrupt request is enabled when FASTAT.CMDLK is set to 1.	R/W
b6, b5	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b7	CFAEIE	Code Flash Memory Access Violation Interrupt Enable	0: Generation of an FIFERR interrupt request is disabled when FASTAT.CFAE is set to 1. 1: Generation of an FIFERR interrupt request is enabled when FASTAT.CFAE is set to 1.	R/W

FAEINT register enables or disables generation of a flash access error (FIFERR) interrupt request.

ECRCTIE Bit (Error Interrupt Enable)

This bit enables or disables generation of an FIFERR interrupt request when a 1-bit error has been corrected in reading of the flash memory area by the flash sequencer (with parameters for configuration setting or programming) or reading of the FCURAM, leading to setting of the FASTAT.ECRCT flag to 1.

DFAEIE Bit (Data Flash Memory Access Violation Interrupt Enable)

This bit enables or disables generation of an FIFERR interrupt request when a data flash memory access violation occurs leading to the FASTAT.DFAE flag being set to 1.

CMDLKIE Bit (Command Lock Interrupt Enable)

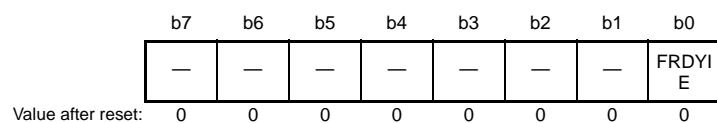
This bit enables or disables generation of an FIFERR interrupt request when the flash sequencer enters the command-locked state leading to the FASTAT.CMDLK flag being set to 1.

CFAEIE Bit (Code Flash Memory Access Violation Interrupt Enable)

This bit enables or disables generation of an FIFERR interrupt request when a code flash memory access violation occurs leading to the FASTAT.CFAE flag being set to 1.

4.4 Flash Ready Interrupt Enable Register (FRDYIE)

Address(es): 007F E018h



Bit	Symbol	Bit Name	Description	R/W
b0	FRDYIE	Flash Ready Interrupt Enable	0: Generation of an FRDY interrupt request is disabled. 1: Generation of an FRDY interrupt request is enabled.	R/W
b7 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

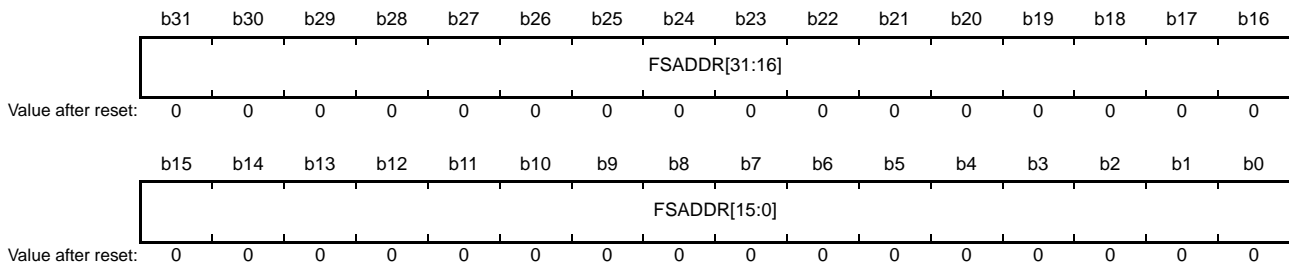
FRDYIE register enables or disables generation of a flash ready (FRDY) interrupt request.

FRDYIE Bit (Flash Ready Interrupt Enable)

This bit is used to enable or disable generation of an FRDY interrupt request when the FASTAT.FRDY flag is changed from 0 to 1 on completion of processing by the flash sequencer of programming and erasure or a blank checking command.

4.5 FACI Command Start Address Register (FSADDR)

Address(es): 007F E030h



Bit	Symbol	Bit Name	Description	R/W	
b31 to b0	FSADDR [31:0]	Start Address for FACI Command Processing	[Command] Programming (code flash memory): Programming (data flash memory): Block erase (code flash memory): Block erase (data flash memory): Blank check: Configuration setting: Lock-bit programming: Lock-bit read:	[Address boundary] 256-byte 4-byte 8-Kbyte or 32-Kbyte 64-byte 4-byte 16-byte 8-Kbyte or 32-Kbyte 8-Kbyte or 32-Kbyte	R/W*1

Note 1. Writing to these bits is only possible when the FSTATR.FRDY flag is 1. Writing to these bits while the FSTATR.FRDY flag = 0 is ignored. Note that b0 and b1 are read-only.

FSADDR register specifies the address where the target area for command processing starts when the FACI command for programming, block erasure, blank checking, configuration setting, lock-bit programming, or lock-bit reading is issued.

The FSADDR register is initialized when the FSUINTR.SUINIT bit is set to 1. It is also initialized by a reset.

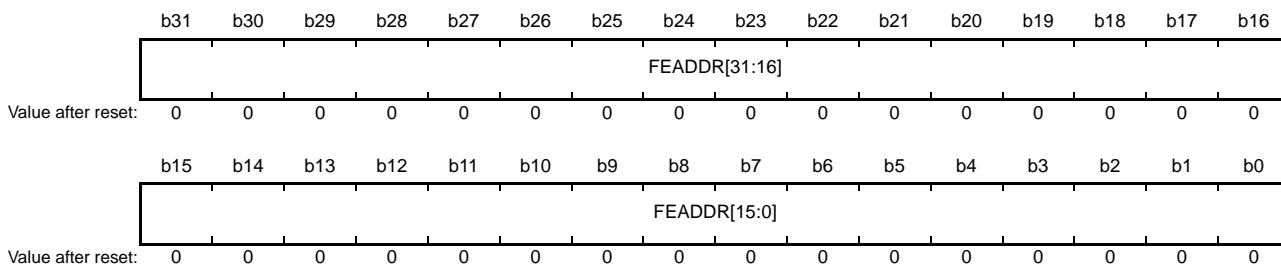
FSADDR[31:0] Bits (Start Address for FACI Command Processing)

These bits specify the start address for FACI command processing. b31 to b24 are ignored in FACI command processing for the code flash memory. b31 to b19 are ignored in FACI command processing for the data flash memory. Bits corresponding to address bits of lower order than the corresponding boundary listed above are also ignored.

Refer to the User's Manual: Hardware for the start addresses of the code flash memory area and data flash memory area. See Table 6.5, Address Used by Configuration Set Command for the start address of the configuration set area

4.6 FACI Command End Address Register (FEADDR)

Address(es): 007F E034h



Bit	Symbol	Bit Name	Description	R/W
b31 to b0	FEADDR [31:0]	End Address for FACI Command Processing	The end address for FACI command processing	R/W*1

Note 1. Writing to these bits is only possible when the FSTATR.FRDY flag is 1. Writing to these bits while the FSTATR.FRDY flag = 0 is ignored. Note that b0 and b1 are read-only.

FEADDR register specifies the address where the target area for blank check command processing ends. When incremental mode is selected as the addressing mode for blank checking (i.e. when FBCCNT.BCDIR = 0), the address specified in the FSADDR register should be smaller than the address in the FEADDR register. Conversely, the address in the FSADDR register should be larger than the address in the FEADDR register when decremental mode is selected as the addressing mode for blank checking (i.e. when FBCCNT.BCDIR = 1). If the settings of the FBCCNT.BCDIR bit and the FSADDR and FEADDR registers are inconsistent with the above rules, the flash sequencer enters the command-locked state (see section 7.2, Error Protection).

The FEADDR register is initialized when the FSUINITR.SUINIT bit is set to 1. It is also initialized by a reset.

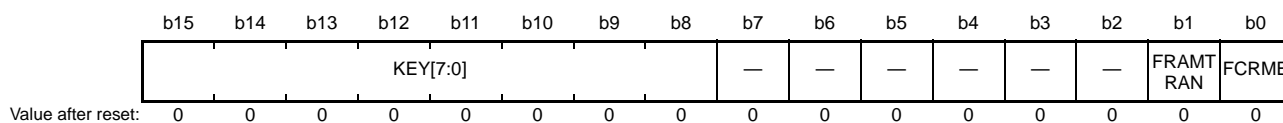
FEADDR[31:0] Bits (End Address for FACI Command Processing)

These bits specify the end address for blank check command processing. b31 to b19, b1, and b0 are ignored in command processing.

Refer to the User's Manual: Hardware for the end address of the data flash memory area.

4.7 FCURAM Enable Register (FCURAME)

Address(es): 007F E054h



Bit	Symbol	Bit Name	Description	R/W
b0	FCRME	FCURAM Enable	0: Disables access to the FCURAM. 1: Enables access to the FCURAM.	R/W*1
b1	FRAMTRAN	FCURAM Transfer Mode	0: Normal transfer mode Both read and write access to the FCURAM are possible. 1: High-speed write mode Only high-speed write access to the FCURAM is possible.	R/W*1
b7 to b2	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b15 to b8	KEY[7:0]	Key Code	Key code	R/W*2

Note 1. Writing to these bits is only possible when 16 bits are written and the value written to the KEY bits is C4h.

Note 2. Written values are not retained by these bits. These bits are read as 0.

FCURAME register enables or disables access to the FCURAM area.

FCRME Bit (FCURAM Enable)

This bit enables or disables access to the FCURAM. Before writing to the FCURAM, stop the flash sequencer by clearing the FENTRYR register to 0000h.

FRAMTRAN Bit (FCURAM Transfer Mode)

This bit specifies the FCURAM transfer mode.

KEY[7:0] Bits (Key Code)

These bits control permission and prohibition of writing to the FRAMTRAN and FCRME bits.

4.8 Flash Status Register (FSTATR)

Address(es): 007F E080h

	b31	b30	b29	b28	b27	b26	b25	b24	b23	b22	b21	b20	b19	b18	b17	b16
	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—
Value after reset:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	b15	b14	b13	b12	b11	b10	b9	b8	b7	b6	b5	b4	b3	b2	b1	b0
	FRDY	ILGLERR	ERSERR	PRGERR	SUSRDY	DBFULL	ERSSPD	PRGSPD	FCUERR	FLWEERR	—	—	—	—	FRDTC	FRCRC
Value after reset:	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

Bit	Symbol	Bit Name	Description	R/W
b0	FRCRCT	1-Bit Error Correction Monitor Flag	0: A 1-bit error correction has not been detected. 1: A 1-bit error correction has been detected.	R
b1	FRDTC	2-Bit Error Detection Monitor Flag	0: A 2-bit error has not been detected. 1: A 2-bit error has been detected.	R
b5 to b2	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b6	FLWEERR	Flash Write/Erase Protect Error Flag	0: An error has not occurred. 1: An error has occurred.	R
b7	FCUERR	FCU Error Flag	0: An error has not occurred during FCU processing. 1: An error has occurred during FCU processing.	R
b8	PRGSPD	Programming Suspend Status Flag	0: The flash sequencer is in a state other than those corresponding to the value 1. 1: The flash sequencer is in the programming suspension processing state or the programming suspended state.	R
b9	ERSSPD	Erase Suspend Status Flag	0: The flash sequencer is in a state other than those corresponding to the value 1. 1: The flash sequencer is in the erasure suspension processing state or the erasure-suspended state.	R
b10	DBFULL	Data Buffer Full Flag	0: The data buffer is empty. 1: The data buffer is full.	R
b11	SUSRDY	Suspend Ready Flag	0: The flash sequencer cannot receive P/E suspend commands. 1: The flash sequencer can receive P/E suspend commands.	R
b12	PRGERR	Programming Error Flag	0: Programming has been completed successfully. 1: An error has occurred during programming.	R
b13	ERSERR	Erase Error Flag	0: Erasure has been completed successfully. 1: An error has occurred during erasure.	R
b14	ILGLERR	Illegal Command Error Flag	0: The flash sequencer has not detected an illegal FACI command or illegal flash memory access. 1: The flash sequencer has detected an illegal FACI command or illegal flash memory access.	R
b15	FRDY	Flash Ready Flag	0: Programming, block erase, P/E suspend, P/E resume, forced stop, blank check, configuration setting, lock-bit programming, or lock-bit read command processing is in progress. 1: None of the above is in progress.	R
b31 to b16	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

FSTATR register indicates the state of the flash sequencer.

FRCRCT Flag (1-Bit Error Correction Monitor Flag)

This flag indicates that a 1-bit error has been corrected by reading FCURAM by the FCU. When the FRCRCT flag is 1, the flash sequencer is not in the command locked state.

[Clearing Condition]

- When the flash sequencer starts processing of a forced stop command.
After the FCU is initialized by issuing a forced stop command, reload the FCU firmware into the FCURAM.

FRDTCT Flag (2-Bit Error Detection Monitor Flag)

This flag indicates that a 2-bit error has been detected by reading FCURAM by the FCU. When the FRDTCT flag is 1, the flash sequencer is in the command locked state.

[Clearing Condition]

- When the flash sequencer starts processing of a forced stop command.
After the FCU is initialized by issuing a forced stop command, reload the FCU firmware into the FCURAM.

FLWEERR Flag (Flash Write/Erase Protect Error Flag)

This flag indicates a violation of the flash memory overwrite protection setting in the FWEPROR register. If this flag is 1, the flash sequencer is in the command-locked state.

[Clearing Condition]

- The flash sequencer starts processing of a forced stop command.

FCUERR Flag (FCU Error Flag)

This flag indicates that an error has occurred during FCU processing. If this flag is 1, the flash sequencer is in the command-locked state.

[Clearing Condition]

- The flash sequencer starts processing of a forced stop command.

When this flag is 1, issue a forced stop command and initialize the FCU, and then reload the FCU firmware into the FCURAM.

PRGSPD Flag (Programming Suspend Status Flag)

This flag indicates that the flash sequencer is in the programming suspension processing state or programming suspended state.

[Setting Condition]

- The flash sequencer starts processing in response to a programming suspend command.

[Clearing Conditions]

- Reception of the P/E resume command by the flash sequencer
(after write access to the FACI command-issuing area is completed).
- The flash sequencer starts processing of a forced stop command.

ERSSPD Flag (Erasure Suspend Status Flag)

This flag indicates that the flash sequencer is in the erasure suspension processing state or erasure suspended state.

[Setting Condition]

- The flash sequencer starts processing in response to an erasure suspend command.

[Clearing Conditions]

- Reception of the P/E resume command by the flash sequencer
(after write access to the FACI command-issuing area is completed).
- The flash sequencer starts processing of a forced stop command.

DBFULL Flag (Data Buffer Full Flag)

This flag indicates the state of the data buffer when a programming command is issued. The FACI incorporates a buffer for write data (data buffer). When data for writing to the flash memory are issued to the FACI command-issuing area while the data buffer is full, the FACI inserts a wait cycle in the peripheral bus 6.

[Setting Condition]

- The data buffer becomes full while programming commands are being issued.

[Clearing Condition]

- The data buffer becomes empty.

SUSRDY Flag (Suspend Ready Flag)

This flag indicates whether the flash sequencer can receive a P/E suspend command.

[Setting Condition]

- After starting programming/erasure processing, the flash sequencer enters a state in which P/E suspend commands can be received.

[Clearing Conditions]

- Reception of the P/E suspend command or forced stop command by the flash sequencer (after write access to the FACI command-issuing area is completed).
- During programming or erasure, the flash sequencer enters the command-locked state.
- Programming or erasure has been completed.

PRGERR Flag (Programming Error Flag)

This flag indicates the result of programming of the flash memory. If this flag is 1, the flash sequencer is in the command-locked state.

[Setting Conditions]

- An error occurs during programming.
- A programming or lock-bit programming command is issued for an area where the lock bit setting is for protection.

[Clearing Condition]

- The flash sequencer starts processing of a status clear or forced stop command.

ERSERR Flag (Erasure Error Flag)

This flag indicates the result of erasure of the flash memory. If this flag is 1, the flash sequencer is in the command-locked state.

[Setting Conditions]

- An error has occurred during erasure.
- A block erase command is issued for an area where the lock bit setting is for protection.

[Clearing Condition]

- The flash sequencer starts processing of a status clear or forced stop command.

ILGLERR Flag (Illegal Command Error Flag)

This flag indicates that the flash sequencer has detected an illegal FACI command or flash memory access. If this flag is 1, the flash sequencer is in the command-locked state.

[Setting Conditions] (See section 7.2, Error Protection)

- The flash sequencer has detected an illegal command.
- The flash sequencer has detected illegal flash memory access.
- The setting of the FENTRYR register is invalid.

[Clearing Condition]

- The flash sequencer starts processing of a status clear or forced stop command while the DFAE and CFAE flag in the FASTAT register is 0.

If the flash sequencer completes processing of a status clear or forced stop command while the CFAE or DFAE flag in the FASTAT register is 1, this flag is set to 1. This flag is temporarily set to 0 during processing of a forced stop command, and is re-set to 1 when the CFAE or DFAE flag is detected as 1 on completion of command processing.

FRDY Flag (Flash Ready Flag)

This flag indicates the command processing state of the flash sequencer.

[Setting Conditions]

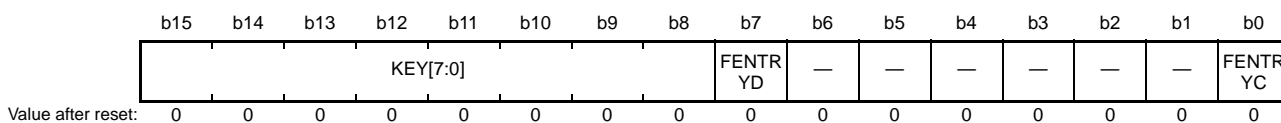
- The flash sequencer completes command processing.
- The flash sequencer receives a P/E suspend command and suspends programming of the flash memory.
- The flash sequencer has received a forced stop command and ended command processing.

[Clearing Conditions]

- The flash sequencer has received an FACI command.
- For programming and configuration setting, the first write access to the FACI command-issuing area.
- For other commands, the last write access to the FACI command-issuing area.

4.9 Flash P/E Mode Entry Register (FENTRYR)

Address(es): 007F E084h



Bit	Symbol	Bit Name	Description	R/W
b0	FENTRYC	Code Flash Memory P/E Mode Entry	0: Code flash memory is in read mode. 1: Code flash memory is in P/E mode.	R/W*1, *2
b6 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b7	FENTRYD	Data Flash Memory P/E Mode Entry	0: Data flash memory is in read mode. 1: Data flash memory is in P/E mode.	R/W*1, *2
b15 to b8	KEY[7:0]	Key Code	Key code	R/W*3

Note 1. Writing to these bits is only possible when the FSTATR.FRDY flag is 1. Writing to these bits while the FSTATR.FRDY flag = 0 is ignored.

Note 2. Writing to these bits is only possible when 16 bits are written and the value written to the KEY bits is AAh.

Note 3. Written values are not retained by these bits. These bits are read as 0.

FENTRYR is used to specify code flash memory P/E mode and data flash memory P/E mode. To specify code flash memory P/E mode or data flash memory P/E mode so that the flash sequencer can receive FACY commands, set either the FENTRYD or FENTRYC bit to 1 to place the flash sequencer in P/E mode.

Note that setting this register to a value other than 0001h and 0080h, the FSTATR.ILGLERR flag will be set to 1, leading to the flash sequencer being placed in the command-locked state.

The FENTRYR register is initialized when the FSUINTR.SUINIT bit is set to 1. It is also initialized by a reset.

FENTRYC Bit (Code Flash Memory P/E Mode Entry)

This bit specifies the P/E mode for code flash memory.

[Setting Condition]

- 1 being written to the FENTRYC bit while writing to FENTRYR is enabled and FENTRYR is 0000h.

[Clearing Conditions]

- 8 bits being written to FENTRYR while the FSTATR.FRDY flag is 1.
- A value other than AAh is specified in the KEY bits and 16 bits are written to FENTRYR while the FSTATR.FRDY flag is 1.
- 0 being written to the FENTRYC bit while writing to FENTRYR is enabled.
- FENTRYR being written to while writing to FENTRYR is enabled and the value of FENTRYR is other than 0000h.

FENTRYD Bit (Data Flash Memory P/E Mode Entry)

This bit specifies the P/E mode for data flash memory.

[Setting Condition]

- 1 being written to the FENTRYR.FENTRYD bit while writing to FENTRYR is enabled and FENTRYR is 0000h.

[Clearing Conditions]

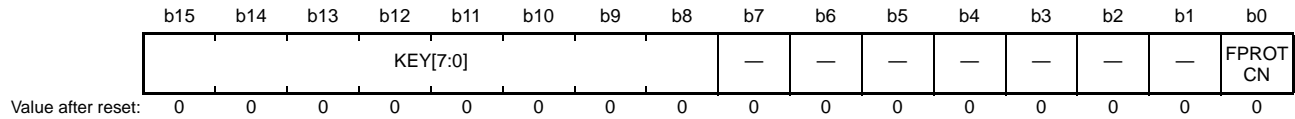
- 8 bits being written to FENTRYR while the FSTATR.FRDY flag is 1.
- Writing of 16 bits to FENTRYR with a value other than AAh specified for the KEY bits while the FSTATR.FRDY flag is 1.
- 0 being written to the FENTRYD bit while writing to FENTRYR is enabled.
- FENTRYR being written to while writing to FENTRYR is enabled and the value of FENTRYR is other than 0000h.

KEY[7:0] Bits (Key Code)

These bits control permission and prohibition of writing to the FENTRYD and FENTRYC bits.

4.10 Flash Protection Register (FPROTR)

Address(es): 007F E088h



Bit	Symbol	Bit Name	Description	R/W
b0	FPROTCN	Lock Bit Protection Cancel	0: Enables protection by the lock bits. 1: Disables protection by the lock bits.	R/W*1
b7 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b15 to b8	KEY[7:0]	Key Code	Key code	R/W*2

Note 1. Writing to these bits is only possible when 16 bits are written and the value written to the KEY bits is 55h.

Note 2. Written values are not retained by these bits. These bits are read as 0.

FPROTR enables or disables protection by the lock bits of the code flash memory against programming and erasure. The FPROTR register is initialized when the FSUINITR.SUINIT bit is set to 1. It is also initialized by a reset.

FPROTCN Bit (Lock Bit Protection Cancel)

This bit enables or disables protection by the lock bits of the code flash memory against programming and erasure.

[Setting Condition]

- 1 being written to the FPROTCN bit while writing to FPROTR is enabled and the value of FENTRYR is other than 0000h.

[Clearing Conditions]

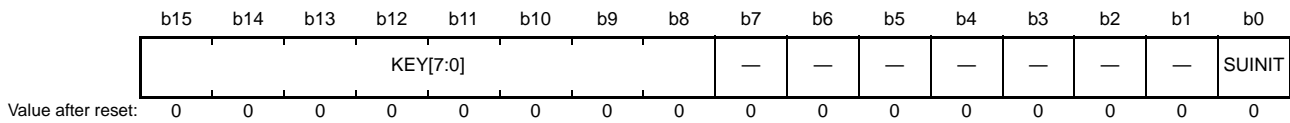
- 8 bits being written to FPROTR
- Writing of 16 bits to FPROTR with a value other than 55h specified for the KEY bits
- 0 being written to the FPROTRCN bit while writing to FPROTR is enabled
- The value of FENTRYR being 0000h

KEY[7:0] Bits (Key Code)

These bits control permission and prohibition of writing to the FPROTCN bit.

4.11 Flash Sequencer Set-Up Initialization Register (FSUINTR)

Address(es): 007F E08Ch



Bit	Symbol	Bit Name	Description	R/W
b0	SUINIT	Set-Up Initialization	0: The FEADDR, FPROTR, FCPSR, FSADDR, FENTRYR, and FBCCNT flash sequencer set-up registers keep their current values. 1: The FEADDR, FPROTR, FCPSR, FSADDR, FENTRYR, and FBCCNT flash sequencer set-up registers are initialized.	R/W*1, *2
b7 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W
b15 to b8	KEY[7:0]	Key Code	Key code	R/W*3

Note 1. Writing to these bits is only possible when the FSTATR.FRDY flag is 1. Writing to these bits while the FSTATR.FRDY flag = 0 is ignored.

Note 2. Writing to these bits is only possible when 16 bits are written and the value written to the KEY bits is 2Dh.

Note 3. Written values are not retained by these bits. This bit is read as 0.

FSUINTR is used for initialization of the flash sequencer set-up.

SUINIT Bit (Set-Up Initialization)

This bit initializes the following flash sequencer set-up registers.

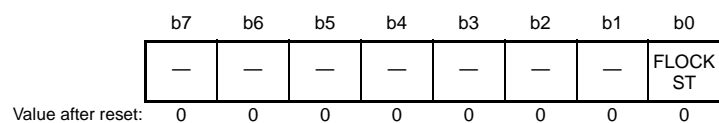
- FEADDR
- FPROTR
- FCPSR
- FSADDR
- FENTRYR
- FBCCNT

KEY[7:0] Bits (Key Code)

These bits control permission and prohibition of writing to the SUINIT bit.

4.12 Lock Bit Status Register (FLKSTAT)

Address(es): 007F E090h



Bit	Symbol	Bit Name	Description	R/W
b0	FLOCKST	Lock Bit Status Flag	0: Protected state 1: Non-protected state	R
b7 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

FLOCKST Flag (Lock Bit Status Flag)

This flag reflects the state of a lock bit as read by executing a lock-bit read command. When the FSTATR.FRDY flag becomes 1 after the lock-bit read command is issued, the value of the target lock bit is stored in the FLOCKST flag. The value of the FLOCKST flag is retained until the next lock-bit read command is completed.

4.13 FACI Command Register (FCMDR)

Address(es): 007F E0A0h



Bit	Symbol	Bit Name	Description	R/W
b7 to b0	PCMDR[7:0]	Precommand Flag	The command immediately before the latest command is stored.	R
b15 to b8	CMDR[7:0]	Command Flag	The latest command is stored.	R

FCMDR records the two most recent commands accepted by the FACI.

PCMDR[7:0] Flags (Precommand Flag)

These flags indicate the command received immediately before the latest command received by the FACI.

CMDR[7:0] Flags (Command Flag)

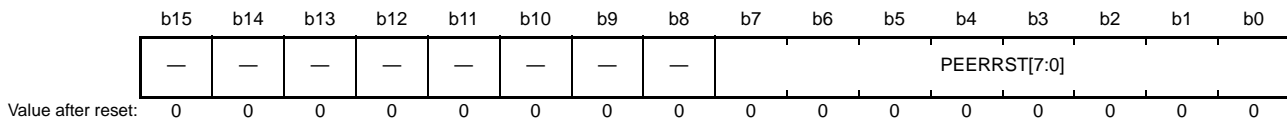
These flags indicate the latest command received by the FACI.

Table 4.2 States of FCMDR after Receiving Commands

Command	CMDR	PCMDR
Programming	E8h	Previous command
Block erase	D0h	20h
P/E suspend	B0h	Previous command
P/E resume	D0h	Previous command
Status clear	50h	Previous command
Forced stop	B3h	Previous command
Blank check	D0h	71h
Configuration setting	40h	Previous command
Lock-bit programming	D0h	77h
Lock-bit read	D0h	71h

4.14 Flash P/E Status Register (FPESTAT)

Address(es): 007F E0C0h



Bit	Symbol	Bit Name	Description	R/W
b7 to b0	PEERRST [7:0]	P/E Error Status Flag	00h: No error 01h: Programming error due to an area being protected by its lock bit 02h: Programming error for reasons other than lock-bit protection 11h: Erasure error due to an area being protected by its lock bit 12h: Erasure error for reasons other than lock-bit protection	R
b15 to b8	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

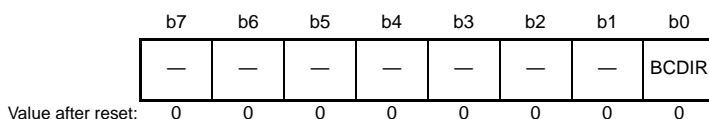
FPESTAT indicates the result of programming or erasure of the flash memory.

PEERRST[7:0] Flags (P/E Error Status Flag)

These flags indicate the source of an error that occurred during processing for the programming or erasure of the code flash memory or data flash memory. The value of these flags is only valid if the ERSERR or PRGERR flag in the FSTATR register is 1 while the FSTATR.FRDY flag is 1. When the ERSERR and PRGERR flags are 0, these flags retain their value to indicate the source of the last error to have occurred.

4.15 Data Flash Blank Check Control Register (FBCCNT)

Address(es): 007F E0D0h



Bit	Symbol	Bit Name	Description	R/W
b0	BCDIR	Blank Check Direction	0: Blank checking is executed from lower addresses to higher addresses (incremental mode). 1: Blank checking is executed from higher addresses to lower addresses (decremental mode).	R/W
b7 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

FBCCNT specifies the addressing mode in processing of a blank check command.

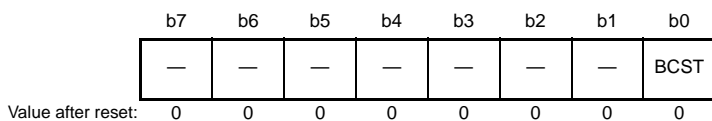
The FBCCNT register is initialized when the FSUINTR.SUINIT bit is set to 1. It is also initialized by a reset.

BCDIR Bit (Blank Check Direction)

This bit specifies the addressing mode for blank checking.

4.16 Data Flash Blank Check Status Register (FBCSTAT)

Address(es): 007F E0D4h



Bit	Symbol	Bit Name	Description	R/W
b0	BCST	Blank Check Status Flag	0: The target area is in the non-programmed state (i.e. is blank; the area has been erased but has not yet been re-programmed). 1: The target area has been programmed with 0s or 1s.	R
b7 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

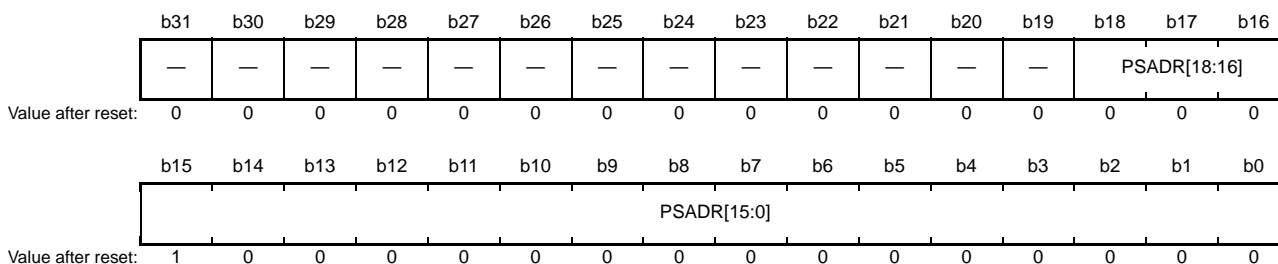
FBCSTAT stores the results of checking in response to a blank check command.

BCST Flag (Blank Check Status Flag)

This flag indicates the results of checking in response to a blank check command.

4.17 Data Flash Programming Start Address Register (FPSADDR)

Address(es): 007F E0D8h



Bit	Symbol	Bit Name	Description	R/W
b18 to b0	PSADR[18:0]	Programmed Area Start Address	The address of the first programmed area	R
b31 to b19	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

FPSADDR indicates the address of the first programmed area to be found in processing of a blank check command.

PSADR[18:0] Bits (Programmed Area Start Address)

These bits indicate the address of the first programmed area to be found in processing of a blank check command. The address is an offset from the address where the data flash memory starts. The setting of these bits is only effective if the FBCSTAT.BCST flag is 1, while the FSTATR.FR DY flag is 1. When the FBCSTAT.BCST flag is 0, the PSADR bit holds the address produced by the previous check.

4.18 Flash Sequencer Processing Switching Register (FCPSR)

Address(es): 007F E0E0h

	b15	b14	b13	b12	b11	b10	b9	b8	b7	b6	b5	b4	b3	b2	b1	b0
	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	ESUSP MD
Value after reset:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

Bit	Symbol	Bit Name	Description	R/W
b0	ESUSPMD	Erasure Suspend Mode	0: Suspension priority mode 1: Erasure priority mode	R/W
b15 to b1	—	Reserved	These bits are read as 0. The write value should be 0.	R/W

FCPSR is for selecting the erasure suspension mode.

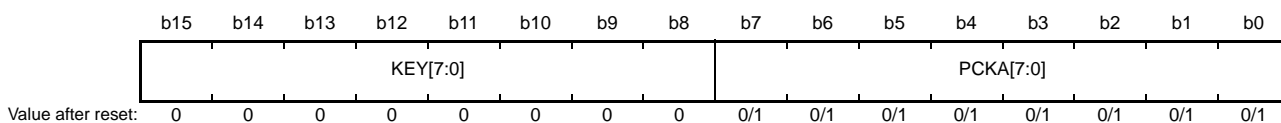
The FCPSR register is initialized when the FSUINTR.SUINIT bit is set to 1. It is also initialized by a reset.

ESUSPMD Bit (Erasure Suspend Mode)

This bit is for selecting the erasure suspension mode when a P/E suspend command is issued while the flash sequencer is executing erasure processing (see section 6.3.10, P/E Suspend Command). This bit should be set before issuing a block erase command.

4.19 Flash Sequencer Processing Clock Notification Register (FPCKAR)

Address(es): 007F E0E4h



Bit	Symbol	Bit Name	Description	R/W
b7 to b0	PCKA[7:0]	Flash Sequencer Operating Clock Notification	These bits are used to set the operating frequency of the flash sequencer while processing FACI commands.	R/W*1, *2
b15 to b8	KEY[7:0]	Key Code	Key code	R/W*3

Note 1. Writing to these bits is only possible when the FSTATR.FRDY flag is 1. Writing to these bits while the FSTATR.FRDY flag = 0 is ignored.

Note 2. Writing to these bits is only possible when 16 bits are written and the value written to the KEY bits is 1Eh.

Note 3. Written values are not retained by these bits. These bits are read as 0.

FPCKAR specifies the operating frequency of the flash sequencer while processing FACI commands. The highest operating frequency for the given product is set as the initial value.

PCKA[7:0] Bits (Flash Sequencer Operating Clock Notification)

These bits specify the operating frequency of the flash sequencer while processing FACI commands. Set the desired frequency in these bits before issuing an FACI command. Specifically, convert the frequency represented in MHz into a binary number and set it in these bits.

Example: Frequency is 35.9 MHz (PCKA = 24h)

Round up the first decimal place of 35.9 MHz to a whole number (= 36) and convert it into a binary number.

If the value set in these bits is smaller than the actual operating frequency of the flash sequencer, the flash memory overwriting characteristics cannot be guaranteed. If the value set in these bits is greater than the actual operating frequency of the flash sequencer, the flash memory overwriting characteristics can be guaranteed but the FACI command processing time such as the time overwriting takes will increase. The minimum FACI command processing time is obtained when the operating frequency of the flash sequencer is the same as the value of the PCKA bit.

KEY[7:0] Bits (Key Code)

These bits control permission and prohibition of writing to the PCKA bit.

5. Operating Modes of the Flash Sequencer

The flash sequencer has three operating modes as shown in Figure 5.1. Transitions between modes are initiated by changing the value of the FENTRYR register.

When the value of the FENTRYR register is 0000h, the flash sequencer is in read mode. In this mode, it does not receive FACI commands. The code flash memory and data flash memory are both readable.

When the value of the FENTRYR register is 0001h, the flash sequencer is in code flash memory P/E mode where the code flash memory can be programmed or erased by FACI commands. In this mode, the data flash memory is not readable. In addition, the code flash memory is not readable if background operation (BGO) is disabled. If BGO is enabled, the code flash memory is readable. As for the condition for enabling BGO, refer to the User’s Manual: Hardware.

When the value of the FENTRYR register is 0080h, the flash sequencer is in data flash memory P/E mode where the data flash memory can be programmed or erased by FACI commands. In this mode, the data flash memory is not readable. However, the code flash memory is readable.

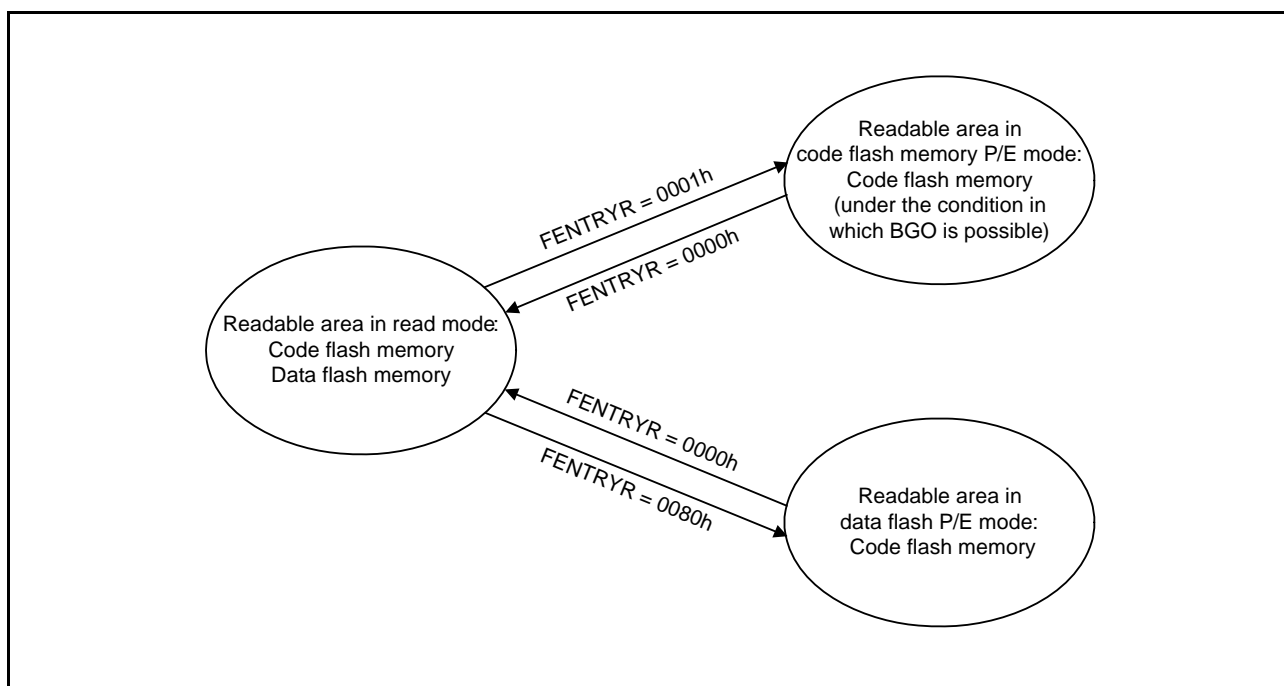


Figure 5.1 Modes of the Flash Sequencer

6. FACI Commands

6.1 List of FACI Commands

Table 6.1 List of FACI Commands

FACI Command	Description
Programming	This is used to program the user area and data area. Units of programming are 256 bytes for the user area and 4 bytes for the data area.
Block erase	This is used to erase the user area, lock bits, or data area. The unit of erasure is one block.
P/E suspend	This suspends programming or erasure processing.
P/E resume	This resumes suspended programming or erasure processing.
Status clear	This initializes the IGLERR, ERSERR, and PRGERR flags in the FSTATR register and releases the flash sequencer from the command-locked state.
Forced stop	This forcibly stops processing of FACI commands and initializes the FSTATR register.
Blank check	This is used to check if data areas are blank. Units of blank checking: 4 bytes to 64 Kbytes (specified in 4-byte units).
Configuration setting	This is used to set the ID, security function, option-setting memory, and trusted memory (TM) function. Units of setting: 16 bytes.
Lock-bit programming	This is used to program the lock bit for a user area. Units of programming: 1 bit (the lock bit for one block)
Lock-bit read	The lock bit for a user area is read and the result is stored in the FLKSTAT register. Units of programming: 1 bit (the lock bit for one block)

The FACI commands are issued by writing to the FACI command-issuing area (see Table 3.1). When write access as shown in Table 6.2 proceeds in the specified state, the flash sequencer executes the processing corresponding to the given command (see section 6.2, Relationship between the Flash Sequencer State and FACI Commands).

Table 6.2 FACI Command Formats

FACI Commands	Number of Write Access	Data to be Written to the FACI Command-Issuing Area			
		1st Access	2nd Access	3rd to (N+2)th Access	(N+3)th Access
Programming (user area) 256-byte programming, N = 128	131	E8h	80h (= N)	WD ₁ to WD ₁₂₈	D0h
Programming (data area) 4-byte programming: N = 2	N + 3	E8h	02h (= N)	WD ₁ to WD _N	D0h
Block erase	2	20h	D0h	—	—
P/E suspend	1	B0h	—	—	—
P/E resume	1	D0h	—	—	—
Status clear	1	50h	—	—	—
Forced stop	1	B3h	—	—	—
Blank check	2	71h	D0h	—	—
Configuration setting N = 8	11	40h	08h (= N)	WD ₁ to WD ₈	D0h
Lock-bit programming	2	77h	D0h	—	—
Lock-bit read	2	71h	D0h	—	—

Note: WD_N (N = 1, 2, ...): Nth 16-bit data to be programmed.

The flash sequencer clears the FSTATR.FRDY flag to 0 at the start of processing of a command other than the status clear command and sets this bit to 1 on completion of command processing.

If the setting of the FRDYIE.FRDYIE bit is 1, a flash ready (FRDY) interrupt is generated when the FSTATR.FRDY flag is set to 1.

6.2 Relationship between the Flash Sequencer State and FCI Commands

The sets of FCI commands that can be accepted in each of the modes/states of the flash sequencer are fixed. FCI commands should be issued after the transition of the flash sequencer to the code flash memory P/E mode or data flash memory P/E mode and checking of the state of the flash sequencer. Use the FSTATR and FASTAT registers to check the state of the flash sequencer. In addition, the occurrence of errors in general can be checked by reading the FASTAT.CMDLK flag; its value is the logical OR of the ILGLERR, ERSERR, PRGERR, FCUERR, FRDTCT, and FLWEERR flags in the FSTATR register.

Table 6.3 lists the available commands in each operating mode.

Table 6.3 Operating Mode and Available Commands

Operating Mode	FENTRYR Register Value	Available Commands
Read mode	0000h	None
Code flash memory P/E mode	0001h	Programming Block erase P/E suspend P/E resume Status clear Forced stop Lock-bit programming Lock-bit read
Data flash memory P/E mode	0080h	Programming Block erase P/E suspend P/E resume Status clear Forced stop Blank check Configuration setting

Table 6.4 shows the state of the flash sequencer and acceptable FACI commands. An appropriate mode is assumed to have been set before the commands are executed.

Table 6.4 Acceptable FACI Commands and the State of the Flash Sequencer

	Processing of Programming or Erasure	Processing of Configuration Setting	Processing to Suspend Programming or Erasure	Blank checking or lock bit reading	Programming Suspended	Erasure Suspended	Programming while Erasure is Suspended	Command-Locked State (FRDY = 1)	Command-Locked State (FRDY = 0)	Lock-Bit Programming	Processing of Forced Stop Command	Other State
FRDY flag	0	0	0	0	1	1	0	1	0	0	0	1
SUSRDY flag	1	0	0	0	0	0	0	0	0	0	0	0
ERSSPD flag	0	0	0/1	0/1	0	1	1	0/1	0/1	0	0	0
PRGSPD flag	0	0	0/1	0/1	1	0	0	0/1	0/1	0	0	0
CMDLK flag	0	0	0	0	0	0	0	1	1	0	0	0
Programming	x	x	x	x	x	○ *3	x	x	x	x	x	○
Block erase	x	x	x	x	x	x	x	x	x	x	x	○
P/E suspend	○	x	x	x	x	x	x	—	x	x	x	—
P/E resume	x	x	x	x	○	○	x	x	x	x	x	x
Status clear	x	x	x	x	○	○	x	○	x	x	x	○
Forced stop	○	○	○	○	○	○	○	○	○	○	○	○
Blank check	x	x	x	x	○ *1	○ *1	x	x	x	x	x	○ *1
Configuration setting	x	x	x	x	x	x	x	x	x	x	x	○ *1
Lock-bit programming	x	x	x	x	x	x	x	x	x	x	x	○ *2
Lock-bit read	x	x	x	x	○ *2	○ *2, *4	x	x	x	x	x	○ *2

○: Acceptable

x: Not acceptable (places the sequencer in the command-locked state)

—: Ignored

Note 1. Only acceptable in data flash memory P/E mode

Note 2. Only acceptable in code flash memory P/E mode

Note 3. Programming is only acceptable for blocks other than blocks where erasure has been suspended.

Note 4. The value read out is undefined when a lock-bit read command is issued for a block where erasure was suspended.

6.3 Usage of FACI Commands

This section gives an overview of the usage of FACI commands.

6.3.1 Overview of Command Usage in Code Flash memory P/E Mode

Figure 6.1 and Figure 6.2 respectively show an overview of FACI command usage in code flash memory P/E mode for products in which background operation (BGO) is possible and that for products in which BGO is not possible. For which commands are available in code flash memory P/E mode, see Table 6.3.

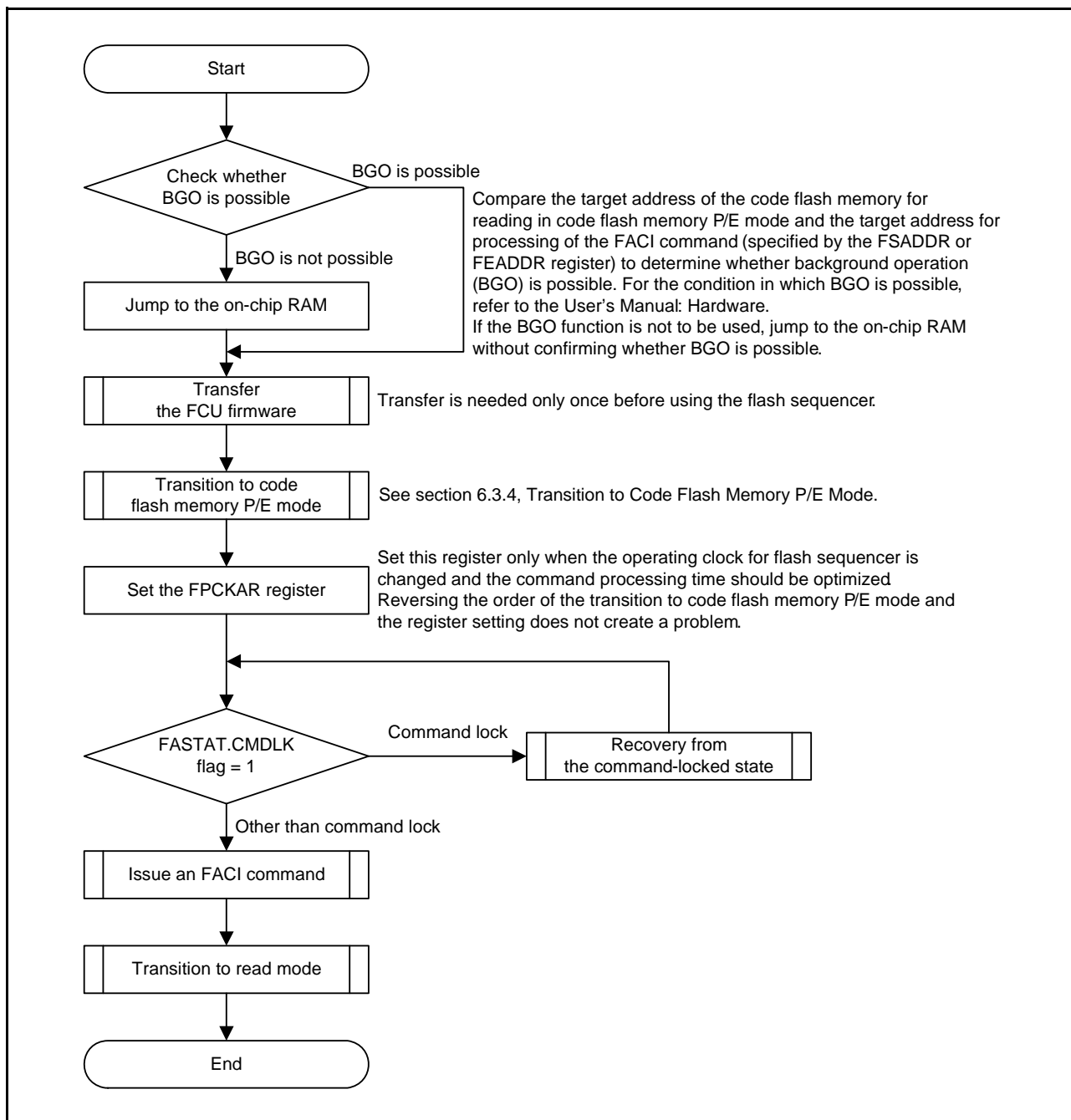


Figure 6.1 Overview of Command Usage in Code Flash Memory P/E Mode (for products in which BGO is possible)

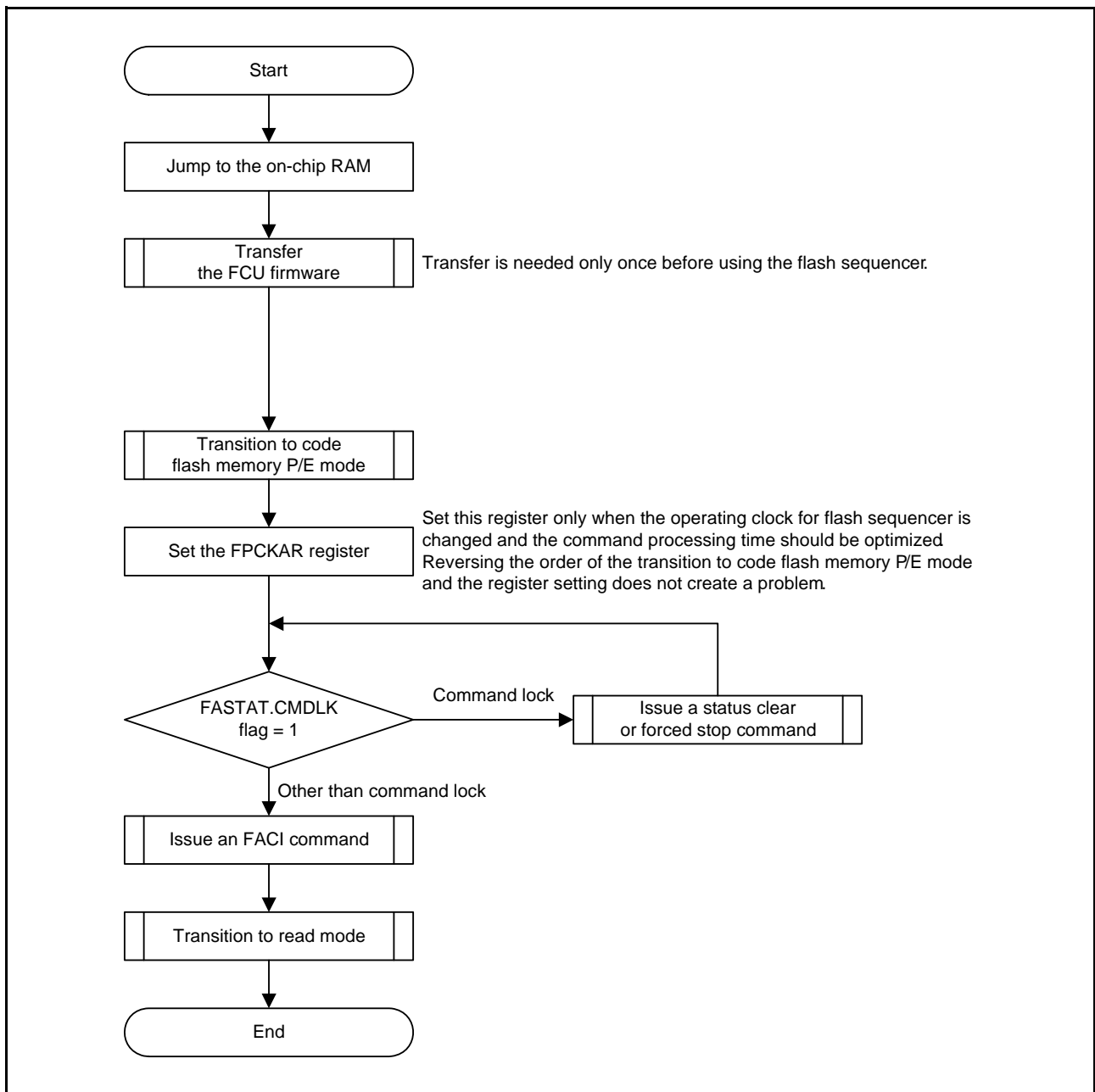


Figure 6.2 Overview of Command Usage in Code Flash Memory P/E Mode (for products in which BGO is not possible)

6.3.2 Overview of Command Usage in Data Flash Memory P/E Mode

An overview of FACI command usage in data flash memory P/E mode is shown below. For which commands are available in data flash memory P/E mode, see Table 6.3.

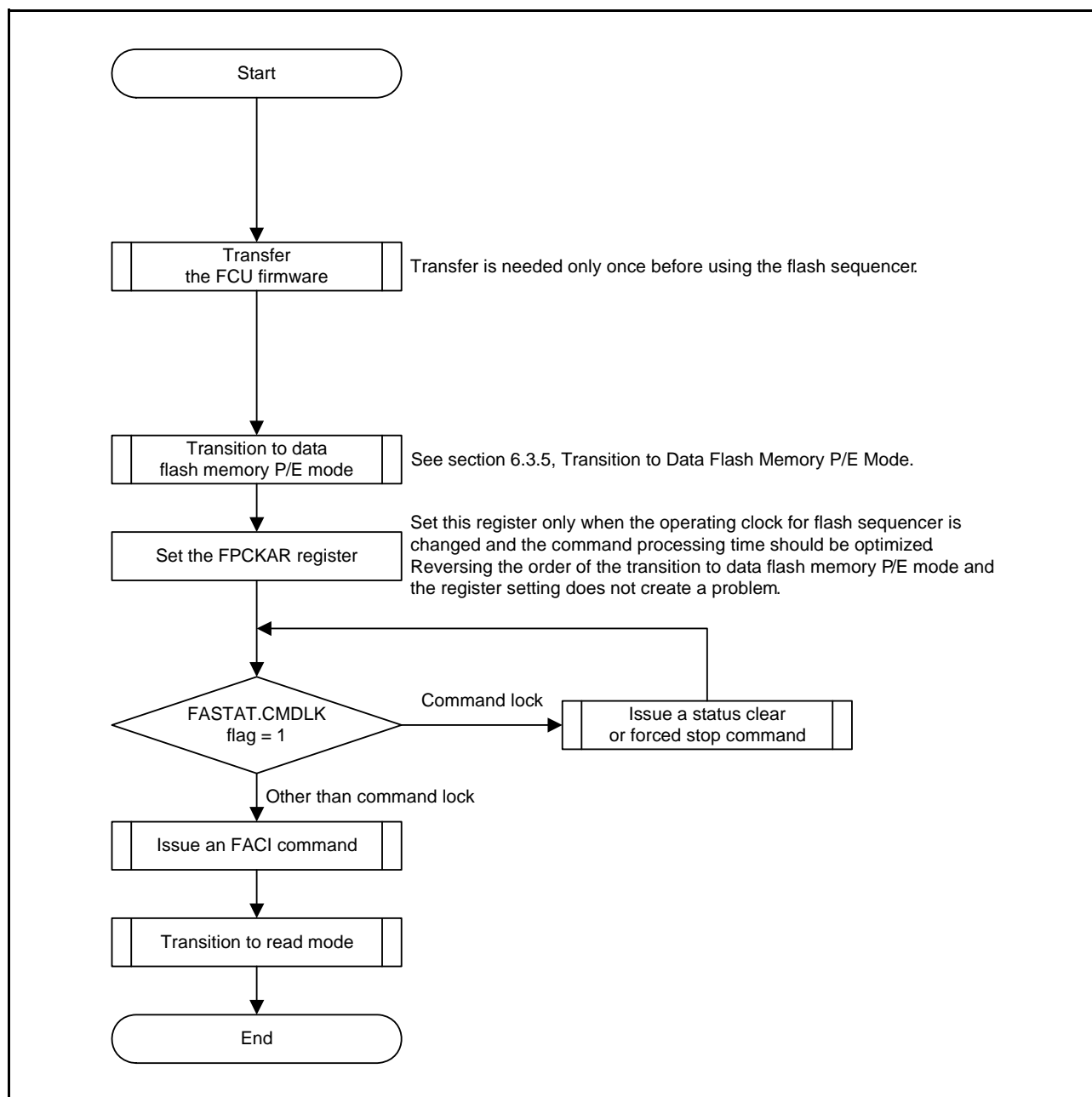


Figure 6.3 Overview of Command Usage in Data Flash Memory P/E Mode

6.3.3 Transferring the FCU Firmware

The flash sequencer can only be used if the FCURAM holds the firmware for the FCU. The FCURAM does not hold the FCU firmware immediately after the chip has been booted up, so the firmware must be copied from the FCU firmware storage area to the FCURAM. Since execution of the FCI command does not update the FCURAM, if the FCU firmware is copied only once before using the flash sequencer, re-updating of the FCURAM is not required.

As data stored in the FCURAM are undefined at boot up, writing to the FCURAM will lead to an ECC error. After copying the FCU firmware, issue a forced stop command and then initialize the FRCRCT and FRDTCT flags in the FSTATR register.

All processing of a forced stop command can be executed by hardware without intervention by the FCU firmware.

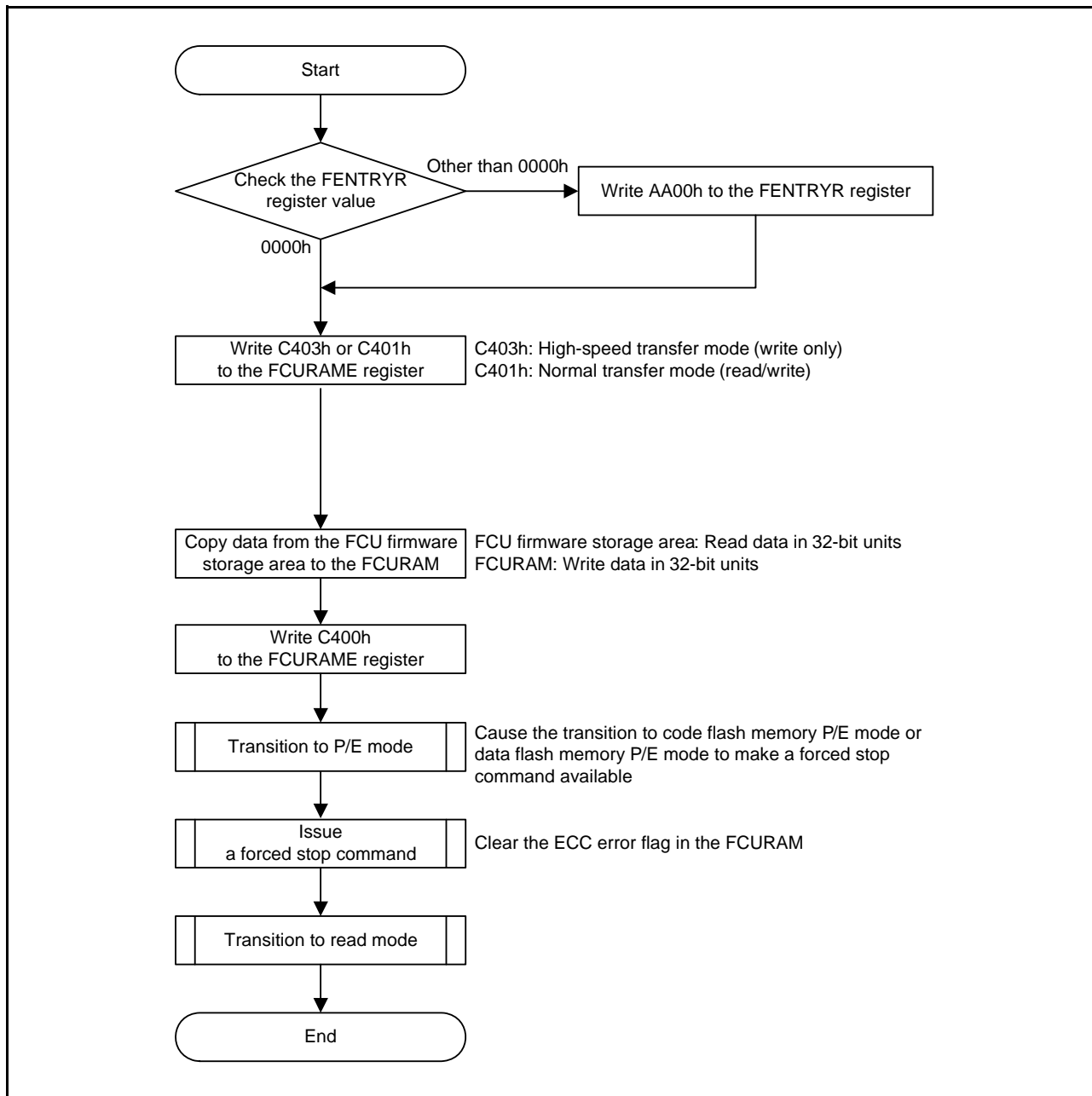


Figure 6.4 Flow for Transferring the FCU Firmware

6.3.4 Transition to Code Flash Memory P/E Mode

To use the FACI commands for the code flash memory, a transition to code flash memory P/E mode is required. To cause the transition to code flash memory P/E mode, set the FENTRYR.FENTRYRC bit to 1.

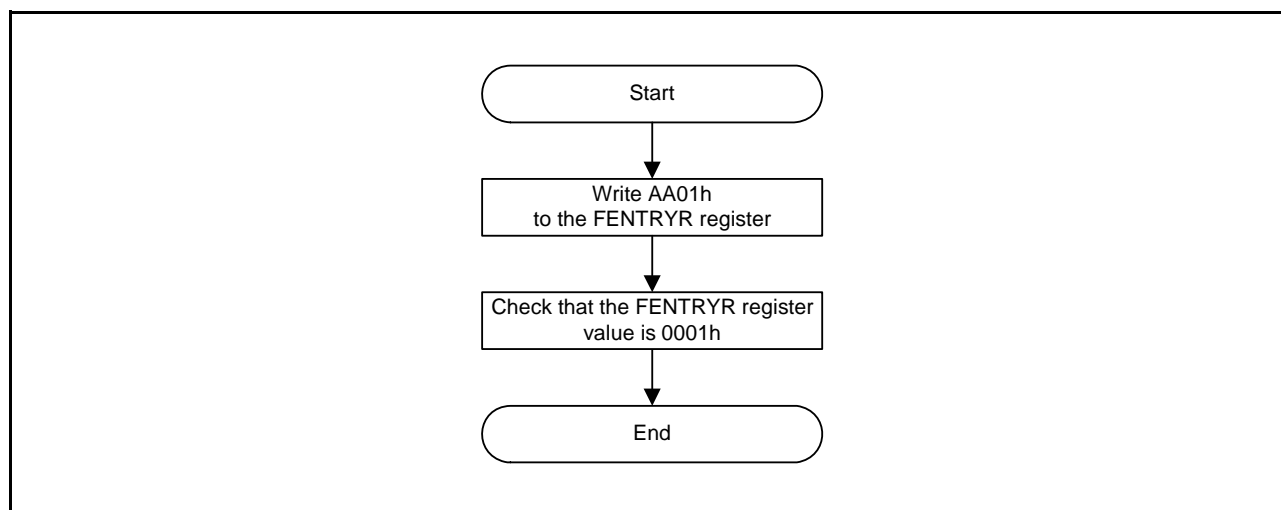


Figure 6.5 Procedure for Transition to Code Flash Memory P/E Mode

6.3.5 Transition to Data Flash Memory P/E Mode

To use the FACI commands for the data flash memory, a transition to data flash memory P/E mode is required. To cause the transition to data flash memory P/E mode, set the FENTRYR.FENTRYRD bit to 1.

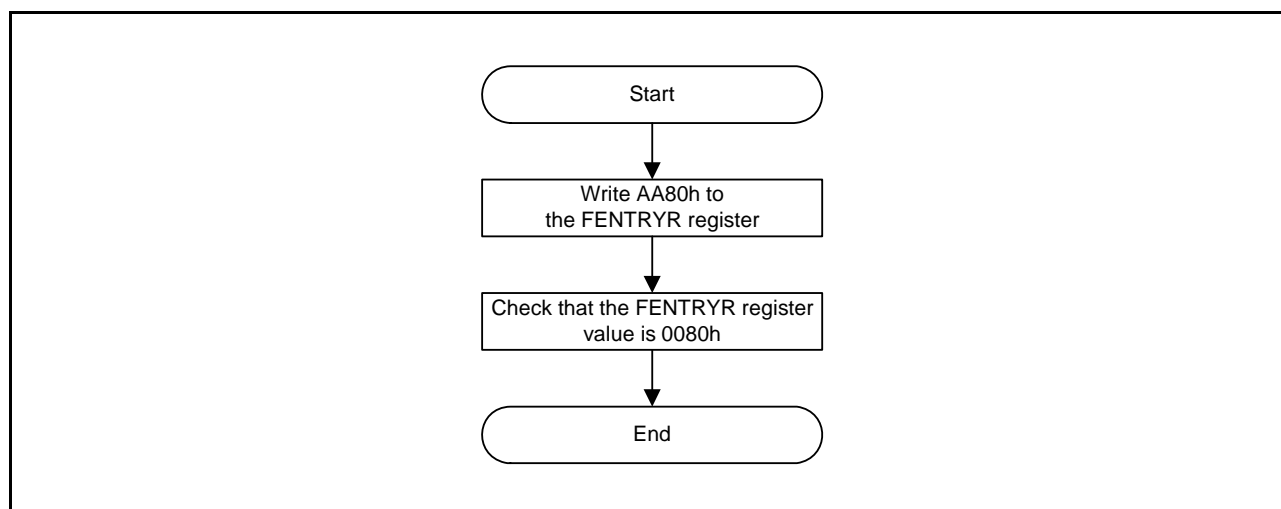


Figure 6.6 Procedure for Transition to Data Flash Memory P/E Mode

6.3.6 Transition to Read Mode

To read the flash memory without using the BGO function, a transition to read mode is required. To cause the transition to read mode, set the FENTRYR register to 0000h. The transition to read mode should be made after processing by the flash sequencer is completed and while operation is in other than in the command-locked state.

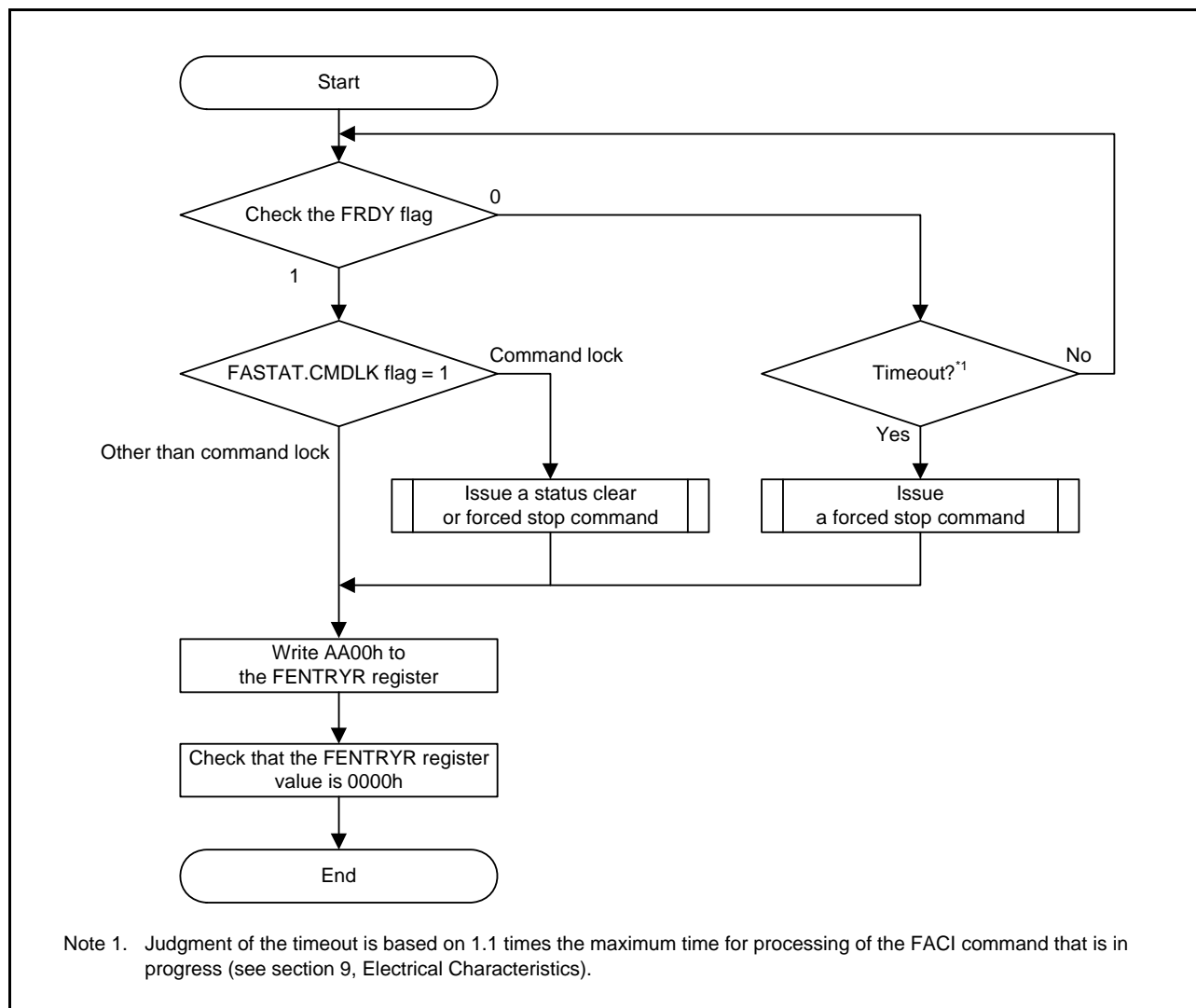


Figure 6.7 Procedure for Transition to Read Mode

6.3.7 Recovery from the Command-Locked State

When the flash sequencer enters the command-locked state, FCI commands cannot be accepted. To release the sequencer from the command-locked state, use the status clear command, forced stop command, or FASTAT register.

When the command-locked state is detected by checking for an error before issuing the P/E suspend command, the FSTATR.FRDY flag may hold 0 although command processing has not been completed. If processing is not completed within the maximum programming/erasure time specified in the User's Manual: Hardware, this can be considered a timeout, and the flash sequencer should be stopped by the forced stop command.

When the FSTATR.ILGLERR flag is 1, check the FASTAT value. If the CFAE or DFAE flag in the FASTAT register is 1, the status clear and forced stop commands cannot be used to release the sequencer from the command-locked state.

The FCUERR, FRDTCT, and FLWERR flags in the FSTATR register are not changed from 1 to 0 by the status clear command. When these bits are set to 1, use the forced stop command for release from the command-locked state. The other bits that indicate the command-locked state can be changed from 1 to 0 by the status clear or forced stop command.

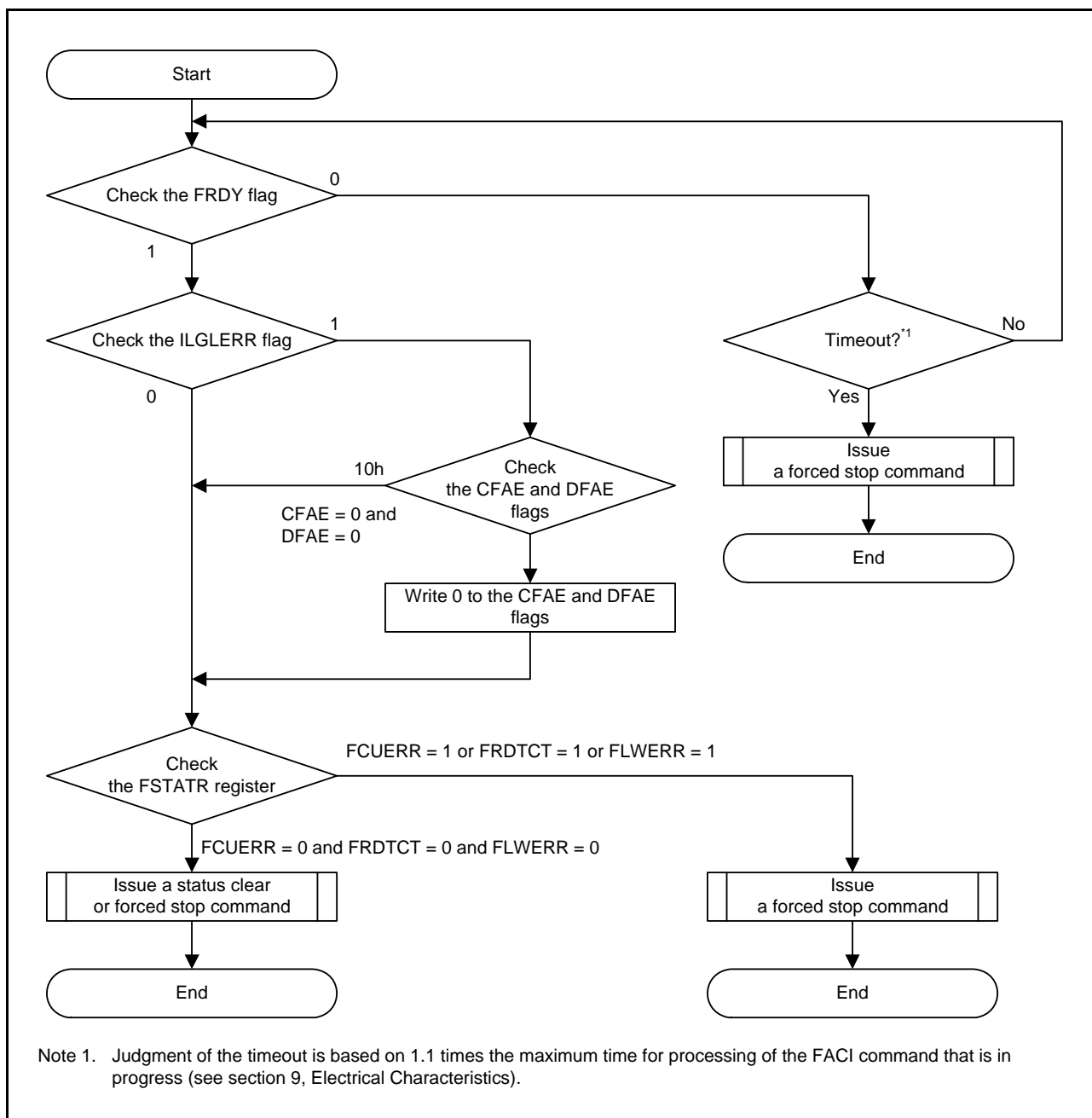


Figure 6.8 Recovery from the Command-Locked State

6.3.8 Programming Command

A programming command is used for writing to the user area and data area.

Before issuing a programming command, set the first address of the target block in the FSADDR register.

Writing D0h to the FCI command-issuing area at the final access of the FCI command-issuing starts the programming command processing. If the target area of programming command processing contains the area not for writing, write FFFFh to the corresponding area.

The FPROTR register must be set before issuing a programming command. To switch between enabling and disabling of the lock bits, the setting of the FPROTR register must be changed.

Issuing a programming command while the FCI internal data buffer is full leads to a wait on the peripheral bus 6, and this may affect the communications performance of other peripheral IP modules. To avoid the generation of a wait in this way, the FSTATR.DBFULL flag should be 0 when an FCI command is issued.

Writing to the data area will not lead to the data buffer becoming full.

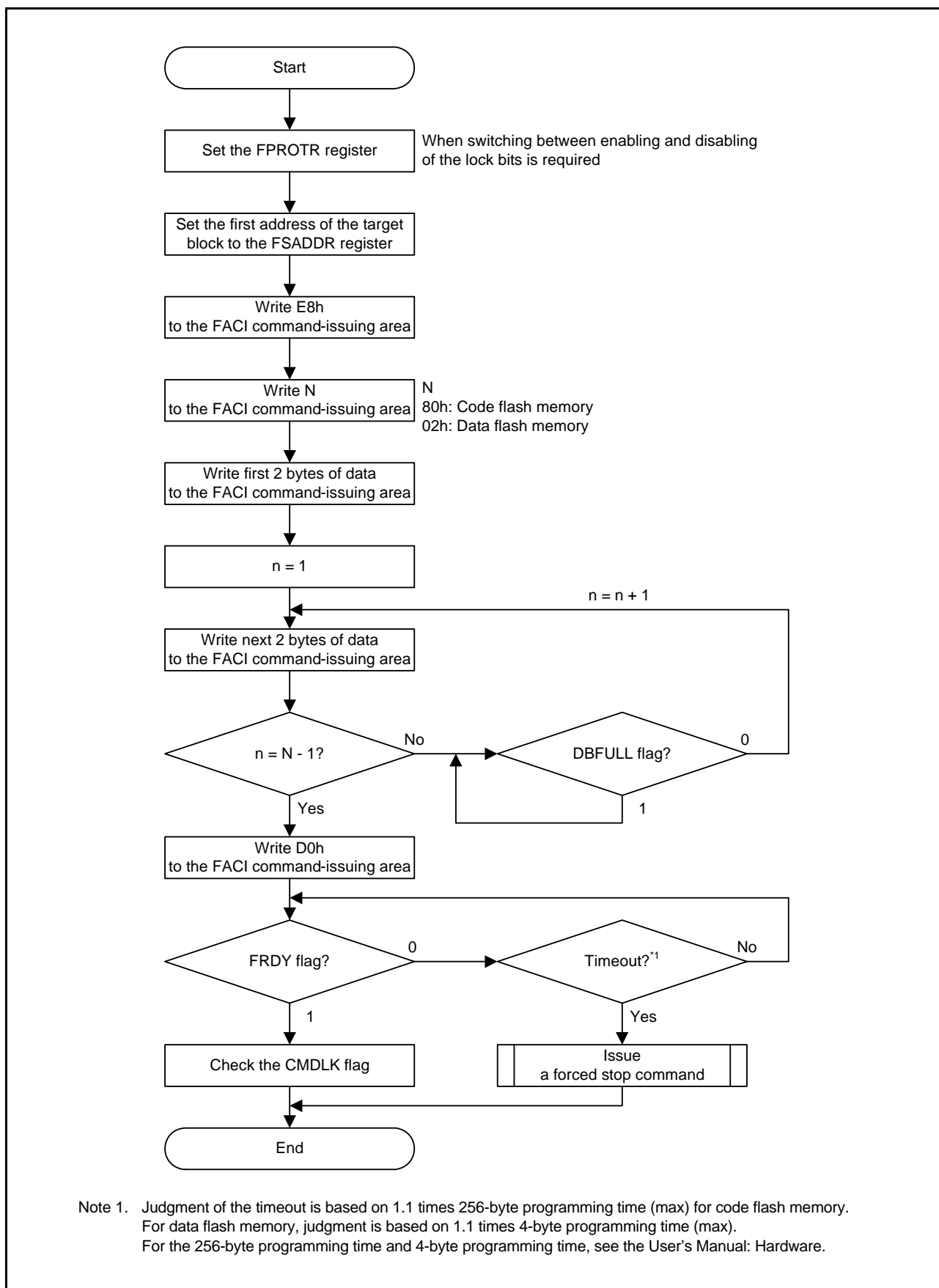


Figure 6.9 Usage of the Programming Command

6.3.9 Block Erase Command

A block erase command is used to erase the user area, lock bit, and data area.

Before issuing a block erase command, set the first address of the target block in the FSADDR register. Writing 20h and D0h to the FCI command-issuing area starts processing of a block erase command.

The FPROTR and FCPSR registers must be set before issuing the block erase command. To switch between enabling and disabling of the lock bits, the setting of the FPROTR register must be changed. To erase the lock bit, issue a block erase command while the FPROTR.FPROTCN bit is 1. The setting of the FCPSR register must be changed to switch the suspending method (suspension priority mode/erasure priority mode) by the P/E suspend command.

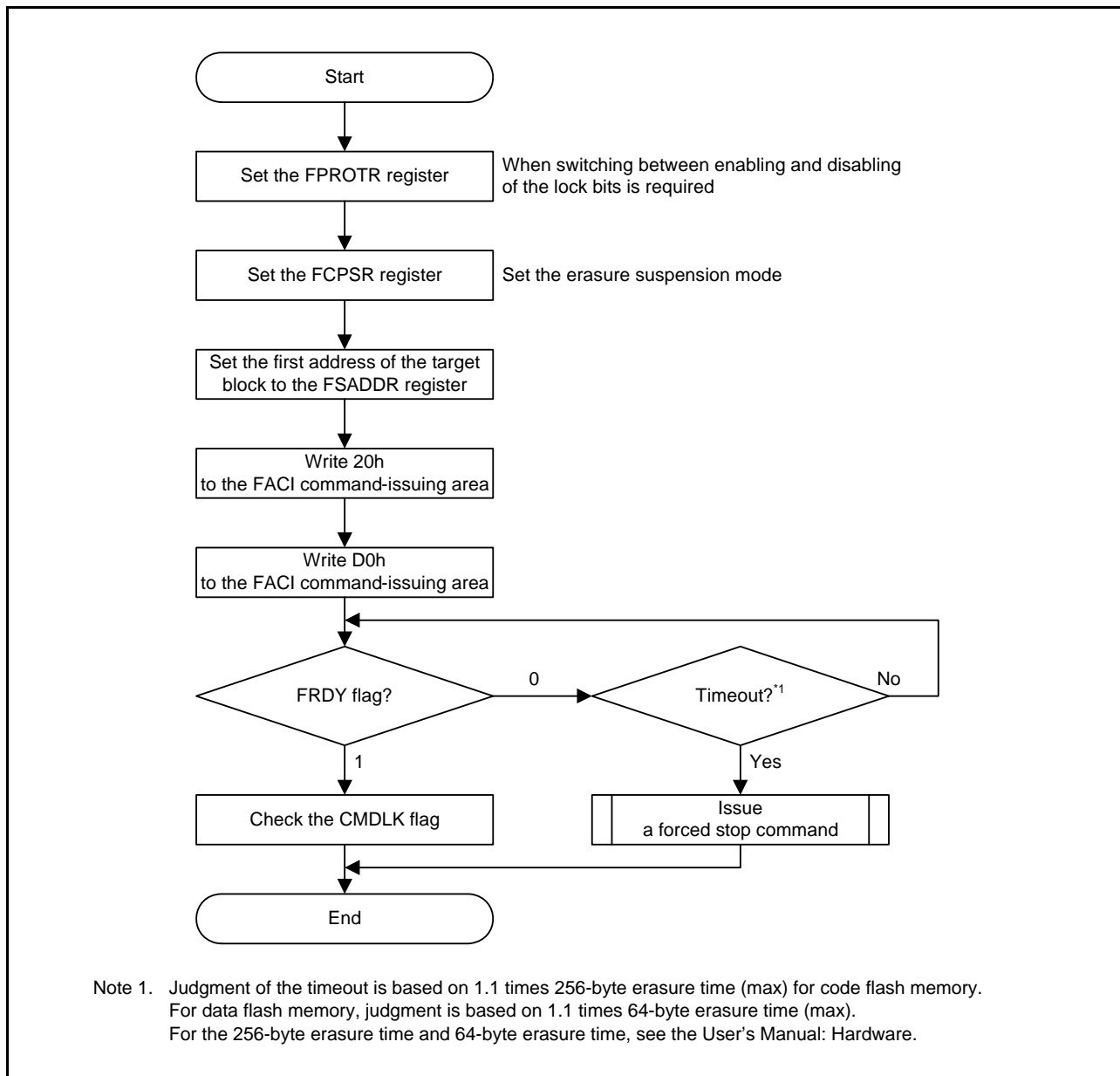


Figure 6.10 Usage of the Block Erase Command

6.3.10 P/E Suspend Command

To suspend programming/erasure, use the P/E suspend command.

Before issuing a P/E suspend command, check that the FASTAT.CMDLK flag is 0, and the execution of programming/erasure is normally performed. To confirm that the P/E suspend command can be received, also check that the FSTATR.SUSRDY flag is 1. After issuing a P/E suspend command, read the FASTAT.CMDLK flag to confirm that its value is 0 (the flash sequencer is not in the command-locked state).

If an error occurs during programming/erasure, the FASTAT.CMDLK flag is set to 1. When programming/erasure processing has finished during the interval from when the FSTATR.SUSRDY flag is checked as 1 to when a P/E suspend command is received, no error occurs and the suspended state is not entered (the FSTATR.SUSRDY flag is 1 and the ERSSPD and PRGSPD flags in FSTATR are 0).

When a P/E suspend command is received and then the programming/erasure suspend processing finishes normally, the flash sequencer enters the suspended state, the FSTATR.SUSRDY flag is set to 1, and the ERSSPD or PRGSPD flag in the FSTATR register is 1. After issuing a P/E suspend command, check that the ERSSPD or PRGSPD flag in the FSTATR register is 1 and the suspended state is entered, and then decide the subsequent flow. If a P/E resume command is issued in the subsequent flow although the suspended state is not entered, an illegal command error occurs and the flash sequencer shifts to the command-locked state (see section 7.2, Error Protection).

If the erasure suspended state is entered, programming to blocks other than an erasure target can be performed.

Additionally, the programming and erasure suspended states can shift to read mode by clearing the FENTRYR register.

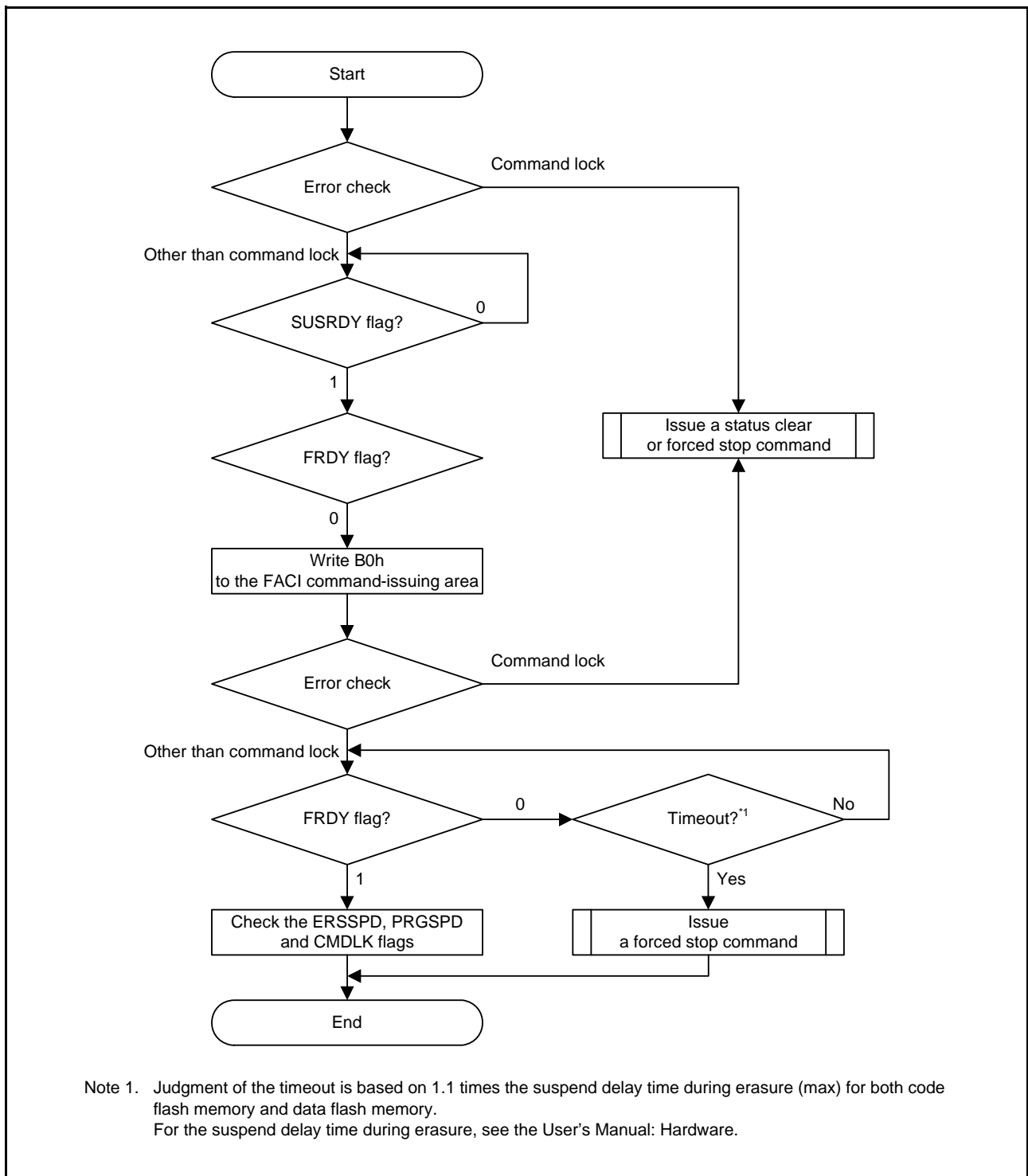


Figure 6.11 Usage of the P/E Suspend Command

(1) Suspension during Programming

When issuing a P/E suspend command during the flash memory programming, the flash sequencer suspends programming processing. Figure 6.12 shows the suspend operation of programming. When receiving a programming-related command, the flash sequencer clears the FSTATR.FRDY flag to 0 to start programming. If the flash sequencer enters the state in which the P/E suspend command can be received after starting programming, it sets the FSTATR.SUSRDY flag to 1. When a P/E suspend command is issued, the flash sequencer receives the command and clears the FSTATR.SUSRDY flag to 0. If the flash sequencer receives a P/E suspend command while a programming pulse is being applied, the flash sequencer continues applying the pulse. After the specified pulse application time, the flash sequencer finishes pulse application, and starts the programming suspend processing and sets the FSTATR.PRGSPD flag to 1.

When the suspend processing finishes, the flash sequencer sets the FSTATR.FRDY flag to 1 to enter the programming suspended state. When receiving a P/E resume command in the programming suspended state, the flash sequencer clears the FSTATR.FRDY and FSTATR.PRGSPD flags to 0 and resumes programming.

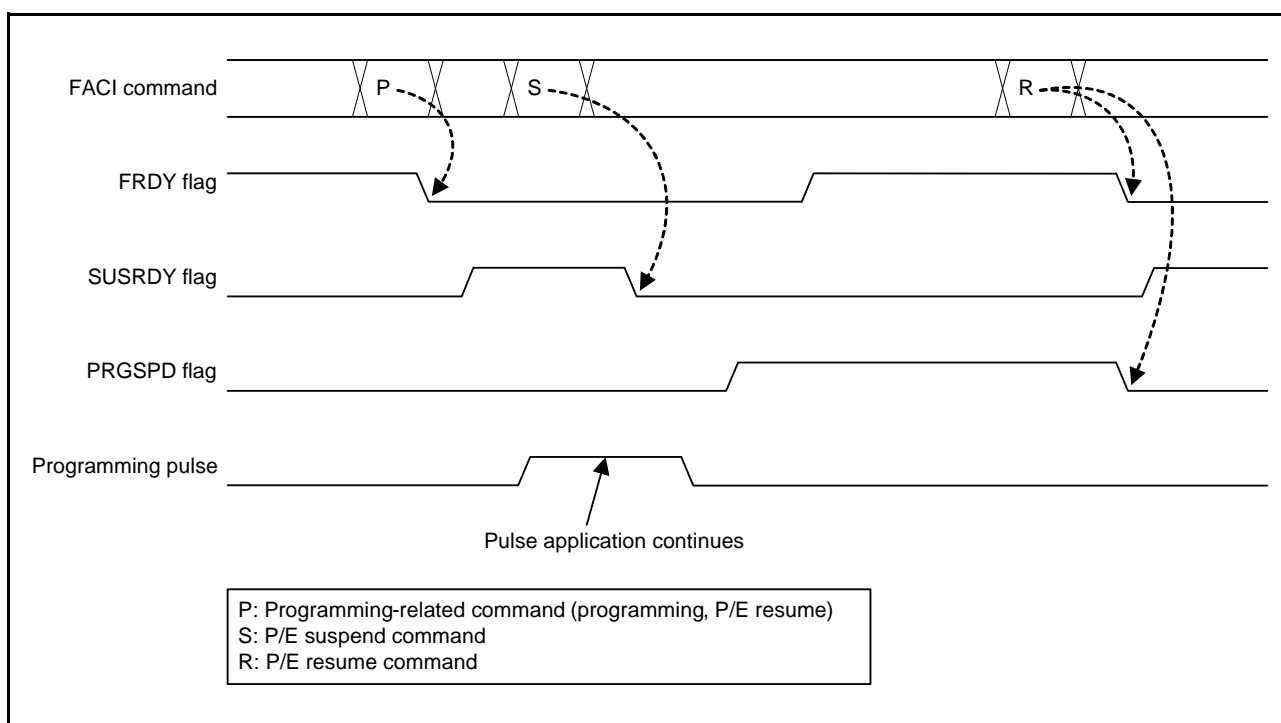


Figure 6.12 Suspension during Programming

(2) Suspension during Erasure (Suspension Priority Mode)

The RX64M Group has a suspension priority mode for the suspension of erasure. Figure 6.13 shows the suspend operation of erasure when the erasure suspend mode is set to the suspension priority mode (the FCPSR.ESUSPMD bit is 0).

When receiving an erasure-related command, the flash sequencer clears the FSTATR.FRDY flag to 0 to start erasure. If the flash sequencer enters the state in which the P/E suspend command can be received after starting erasure, it sets the FSTATR.SUSRDY flag to 1. When a P/E suspend command is issued, the flash sequencer receives the command and clears the FSTATR.SUSRDY flag to 0. When receiving a suspend command during erasure, the flash sequencer starts the suspend processing and sets the FSTATR.ERSSPD flag to 1 even if it is applying an erasure pulse. When the suspend processing finishes, the flash sequencer sets the FSTATR.FRDY flag to 1 to enter the erasure suspended state. When receiving a P/E resume command in the erasure suspended state, the flash sequencer clears the FRDY and ERSSPD flags in the FSTATR register to 0 and resumes erasure. Operations of the FRDY, SUSRDY, and ERSSPD flags in the FSTATR register at the suspension and resumption of erasure are the same, regardless of the erasure suspend mode.

The setting of the erasure suspend mode affects the control method of erasure pulses. In suspension priority mode, when receiving a P/E suspend command while erasure pulse A that has never been suspended in the past is being applied, the flash sequencer suspends the application of erasure pulse A and enters the erasure suspended state. When receiving a P/E suspend command while reapplying erasure pulse A after erasure is resumed by a P/E resume command, the flash sequencer continues applying erasure pulse A. After the specified pulse application time, the flash sequencer finishes erasure pulse application and enters the erasure suspended state. When the flash sequencer receives a P/E resume command next and erasure pulse B starts to be newly applied, and then the flash sequencer receives a P/E suspend command again, the application of erasure pulse B is suspended. In suspension priority mode, delay due to suspension can be minimized because the application of an erasure pulse is suspended one time per pulse and priority is given to the suspend processing.

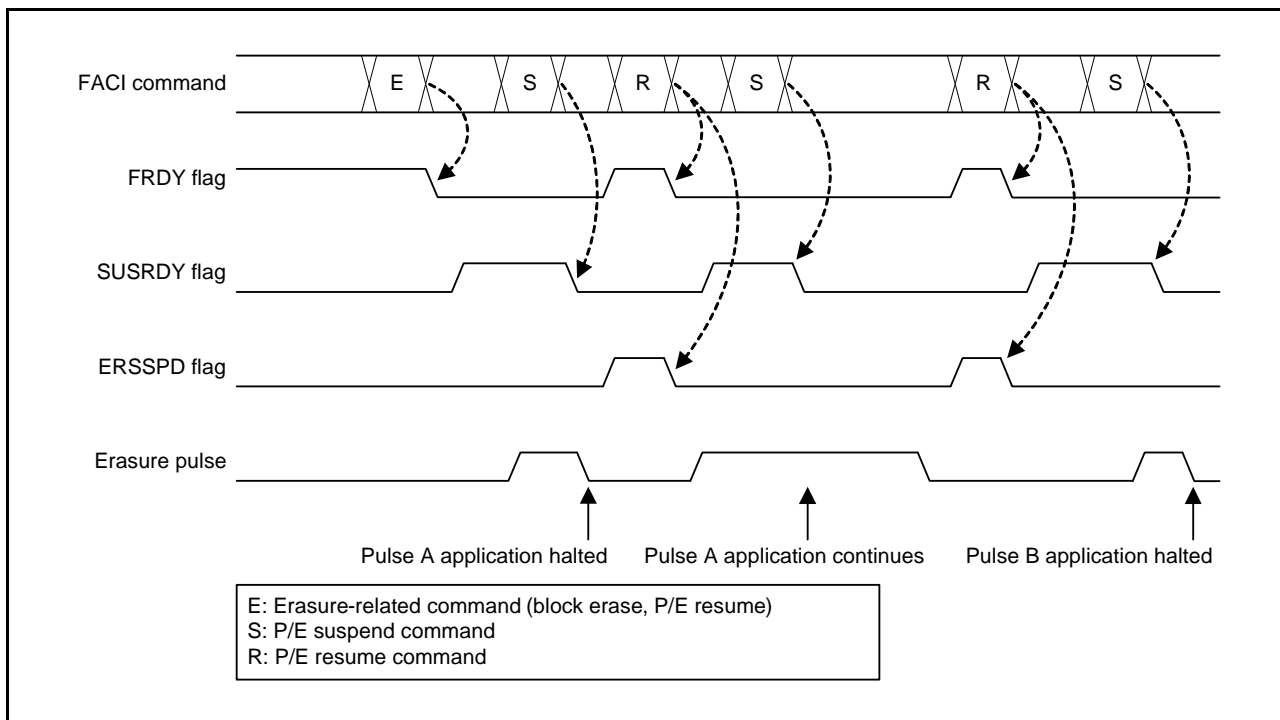


Figure 6.13 Suspension during Erasure (Suspension Priority Mode)

(3) Suspension during Erasure (Erasure Priority Mode)

The RX64M Group has an erasure priority mode for the suspension of erasure.

Figure 6.14 shows the suspend operation of erasure when the erasure suspend mode is set to the erasure priority mode (the FCPSR.ESUSPMD bit is 1). The control method of erasure pulses in erasure priority mode is the same as that of programming pulses for the programming suspend processing.

If the flash sequencer receives a P/E suspend command while an erasure pulse is being applied, the flash sequencer definitely continues applying the pulse. In this mode, the required time for the whole erasure processing can be reduced as compared with the suspension priority mode because the reapplication of erasure pulses does not occur when a P/E resume command is issued.

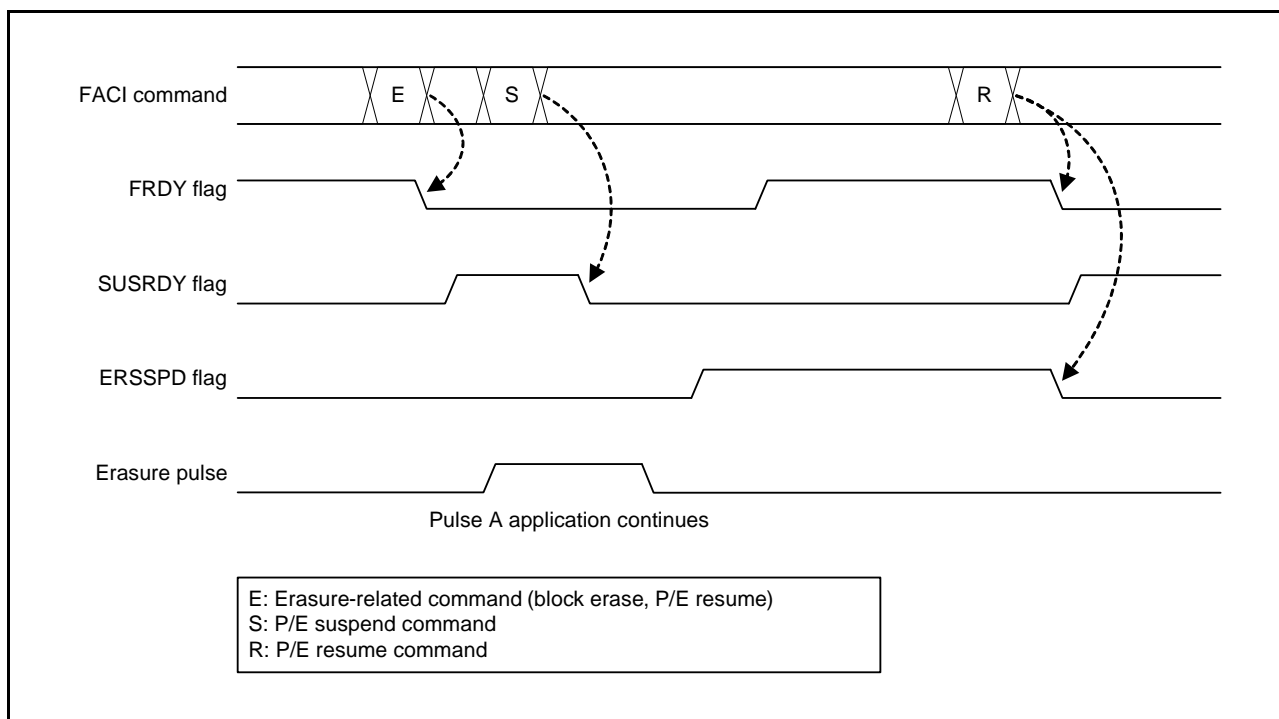


Figure 6.14 Suspension during Erasure (Erasure Priority Mode)

6.3.11 P/E Resume Command

To resume suspended programming or erasure, use the P/E resume command. When the settings of the FENTRYR register are changed during suspension, reset FENTRYR to the value immediately before the P/E suspend command was issued, and then issue a P/E resume command.

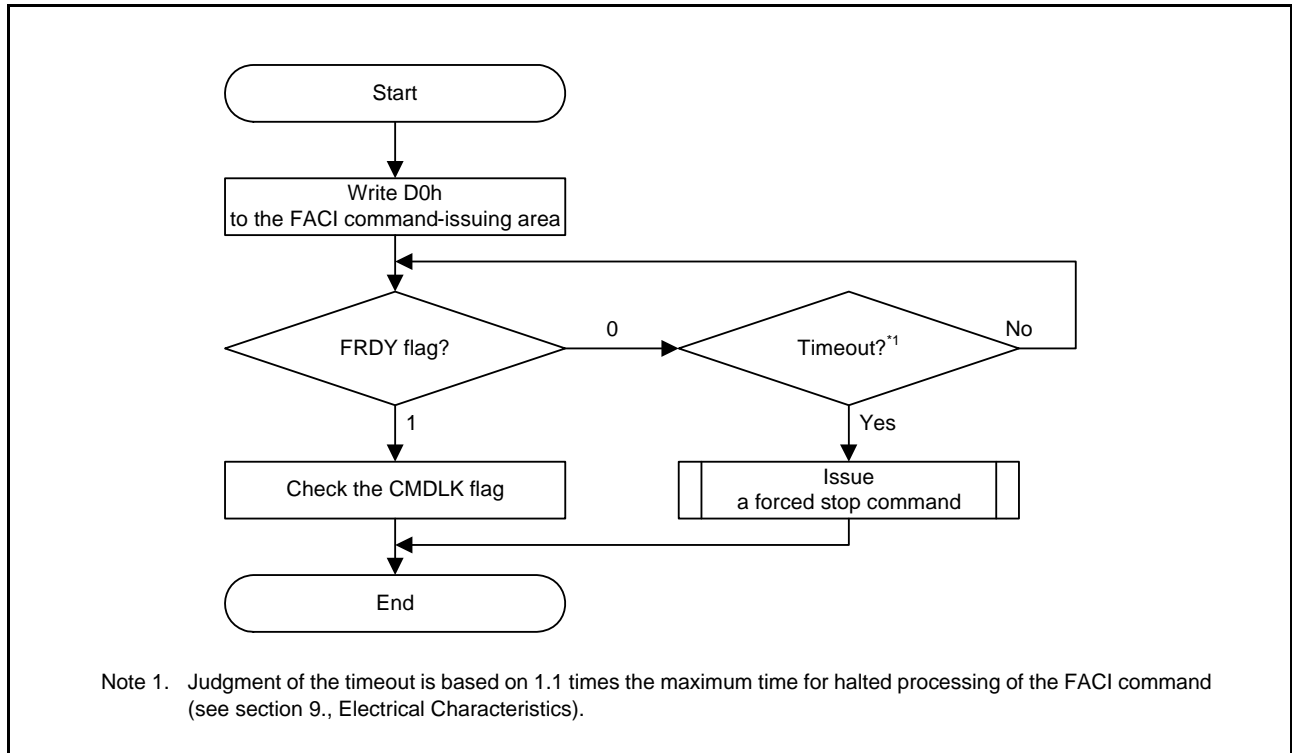


Figure 6.15 Usage of the P/E Resume Command

6.3.12 Status Clear Command

The status clear command is used to clear the command-locked state (see section 6.3.7, Recovery from the Command-Locked State). To clear the ILGLERR, ERSERR, and PRGERR flags in the FSTATR register in the command-locked state, the status clear command is available. All processing of a status clear command can be executed by hardware without intervention by the FCU firmware.

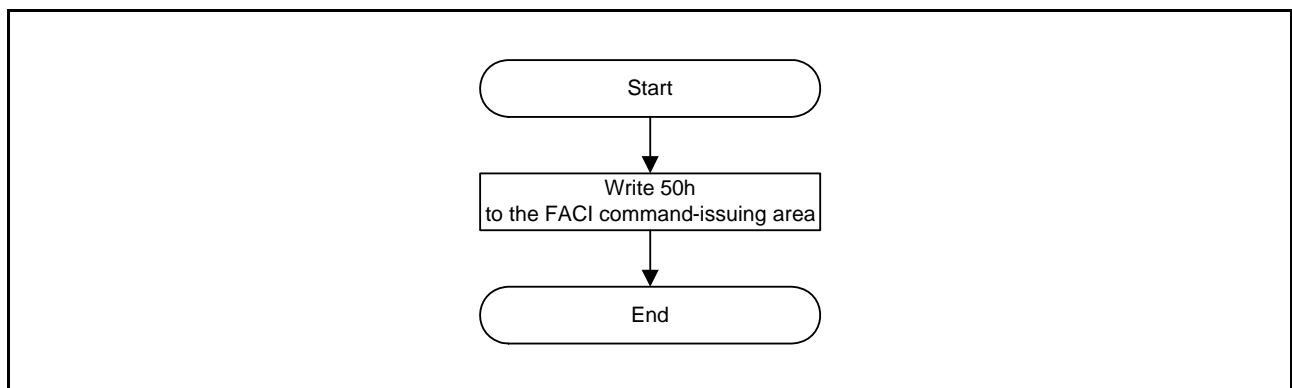


Figure 6.16 Usage of the Status Clear Command

6.3.13 Forced Stop Command

The forced stop command forcibly ends command processing by the flash sequencer. Although this command halts command processing more quickly than the P/E suspension command, values from the area where programming or erasure was in progress are not guaranteed. Furthermore, resumption of processing is not possible. Processing of programming or erasure that was halted by the forced stop command is also defined as one round of programming. Executing a forced stop command also initializes part of the FCI, the whole FCU, and the FSTATR. Accordingly, this command can be used in the procedure for recovery from the command-locked state and in processing in response to a time-out of the flash sequencer (see section 6.3.7, Recovery from the Command-Locked State)

All processing of a forced stop command can be executed by hardware without intervention by the FCU firmware.

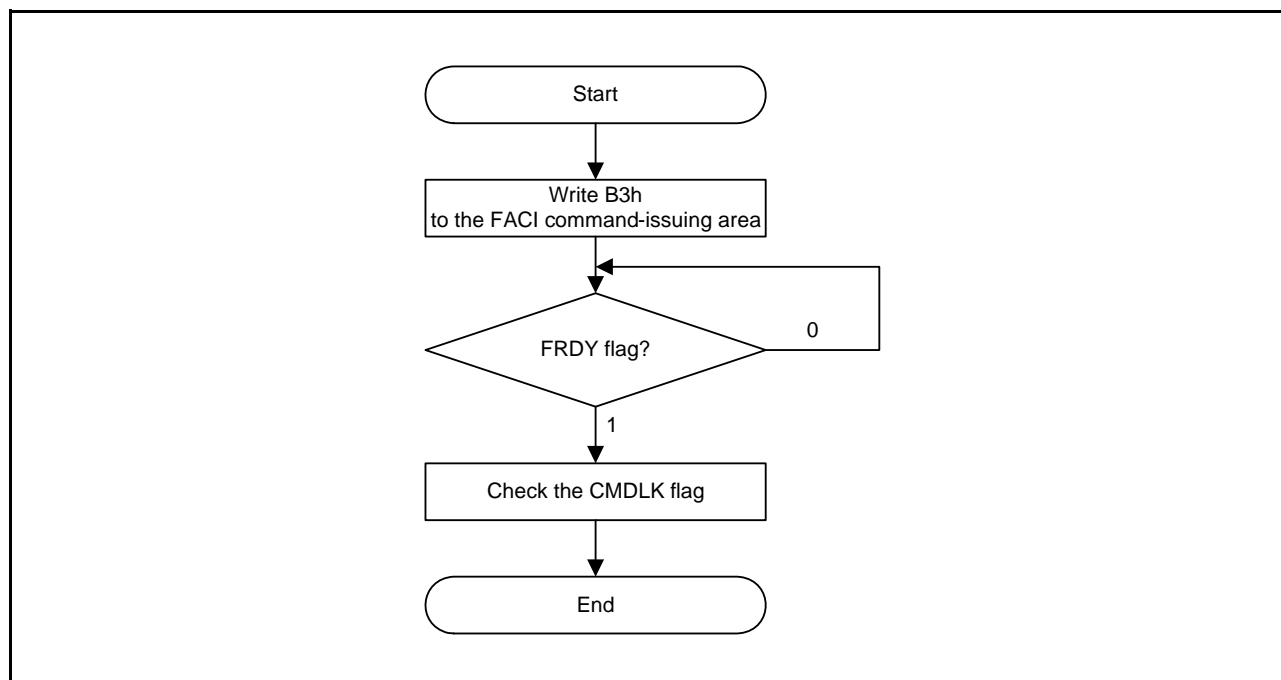


Figure 6.17 Usage of the Forced Stop Command

6.3.14 Blank Check Command

Values read from data flash memory that has been erased but not yet been programmed again (i.e. that is in the non-programmed state) are undefined. Use the blank check command when you need to confirm that an area is in the non-programmed state.

Before issuing a blank check command, set addressing mode, start address, and end address of the target area for blank checking to the FBCCNT, FSADDR, and FEADDR registers. When blank checking addressing mode is set to decremental mode (i.e. FBCCNT.BCDIR = 1), address specified in FSADDR should be larger than address in FEADDR. Conversely, address in FSADDR should be smaller than address in FEADDR when blank check addressing mode is set to incremental mode (i.e. FBCCNT.BCDIR = 0).

If the settings of the FBCCNT.BCDIR bit, FSADDR, and FEADDR are inconsistent, the flash sequencer enters the command-locked state. The size of the target area for blank checking is in the range from 4 bytes to 64 Kbytes and is set in units of 4 bytes.

Write 71h and D0h to the FCI command-issuing area to start blank checking. Completion of processing can be confirmed by the FSTATR.FRDY flag. At the end of processing, the result of blank checking is stored in the FBCSTAT.BCST flag. If the target area for blank checking includes areas where programming has been completed, the flash sequencer stores the address of the first such area it detects in the FPSADDR register.

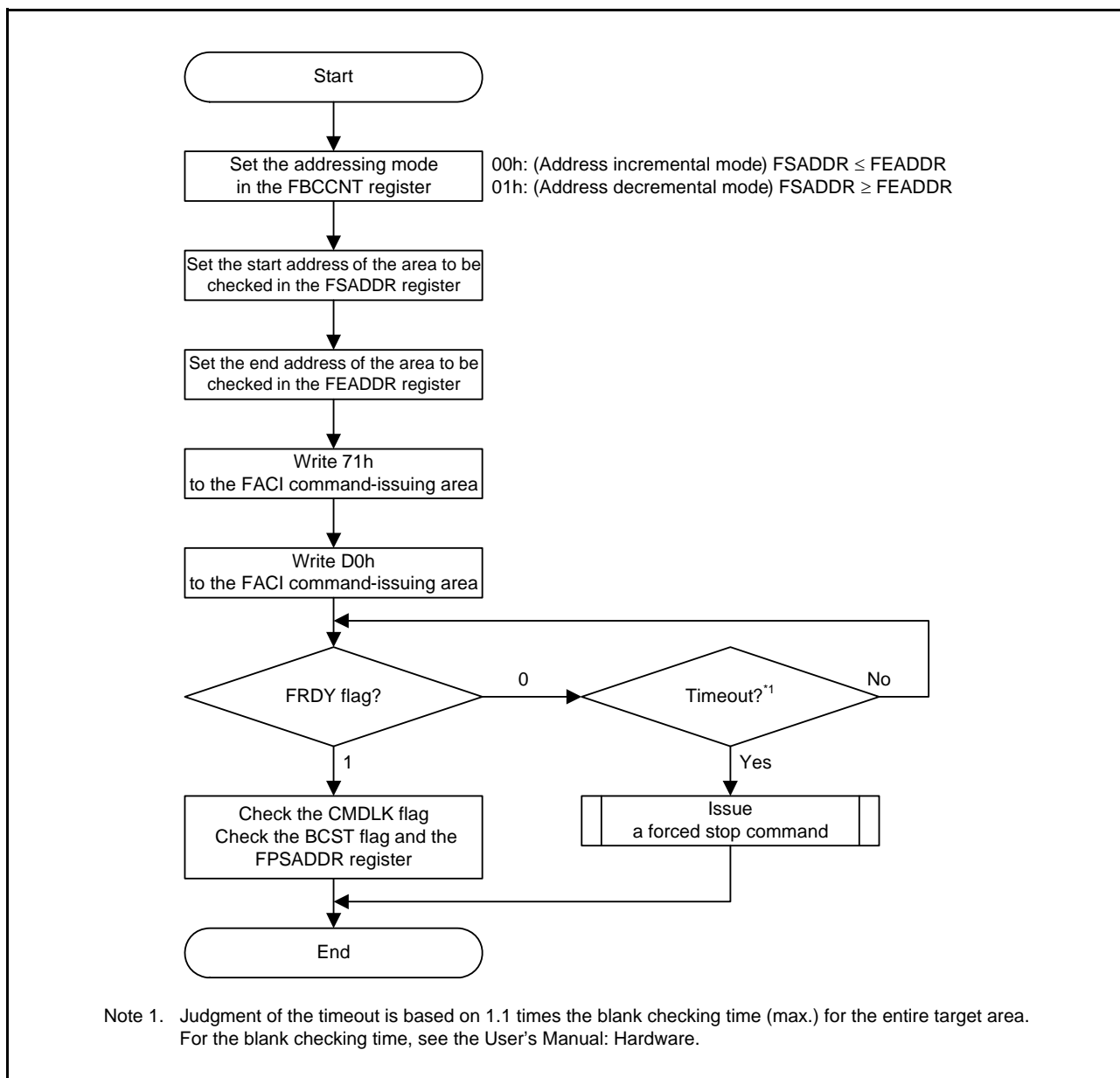


Figure 6.18 Usage of the Blank Check Command

6.3.15 Configuration Set Command

The configuration set command is used to set the ID, security function, option-setting memory, and TM function. Before issuing a configuration set command, set the specified address (shown in Table 6.5) in the FSADDR register. Writing D0h to the FACI command-issuing area in the final access for issuing the FACI command starts processing of the configuration set command.

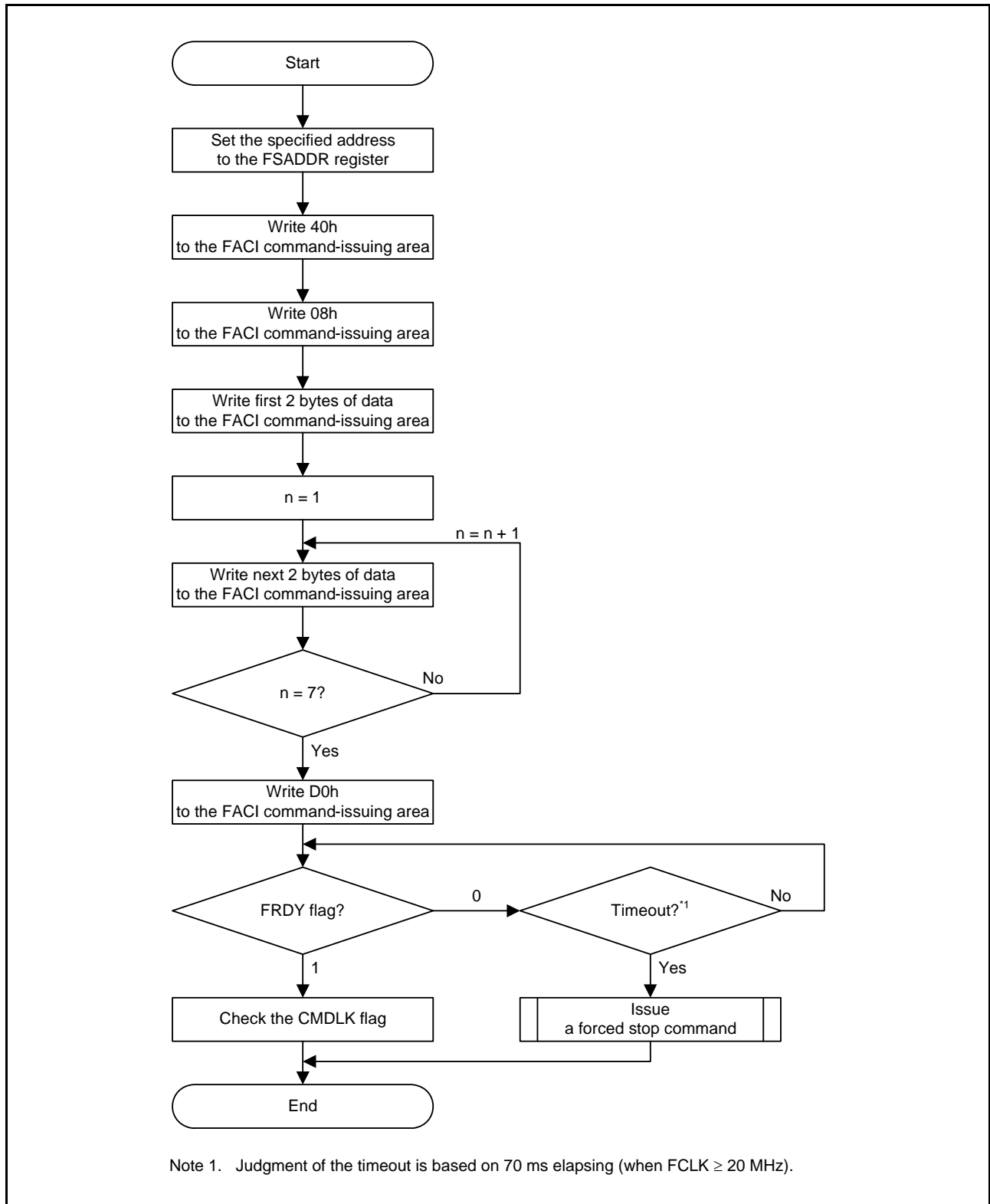


Figure 6.19 Usage of the Configuration Set Command

The correspondence between the possible target data for configuration setting and the address value set in the FSADDR register is shown in Table 6.5. For details on the FSADDR register, see section 4.5, FCI Command Start Address Register (FSADDR). Data in other areas can be changed to any value each time the configuration set command is executed.

Table 6.5 Address Used by Configuration Set Command

Address	FSADDR	
	Register Value	Setting Data
0012 0040h	0000 0040h	Serial programmer command control register (SPCC), TM enable flag register (TMEF)
0012 0050h	0000 0050h	ID for authentication (OSIS)
0012 0060h	0000 0060h	TM identification data register (TMINF), option function selection (OFS0, OFS1), endian selection (MDE)

6.3.16 Lock-Bit Programming Command

To write to a lock bit, use the lock-bit programming command. To erase a lock bit, use the block erase command (see section 6.3.9, Block Erase Command).

Before issuing a lock-bit programming command, set the first address of the target block in the FSADDR register.

Writing 77h and D0h to the FCI command-issuing area starts processing of a lock-bit programming command.

The FPROTR register must be set before issuing a lock-bit programming command. To switch between enabling and disabling of the lock bits, the setting of the FPROTR register must be changed.

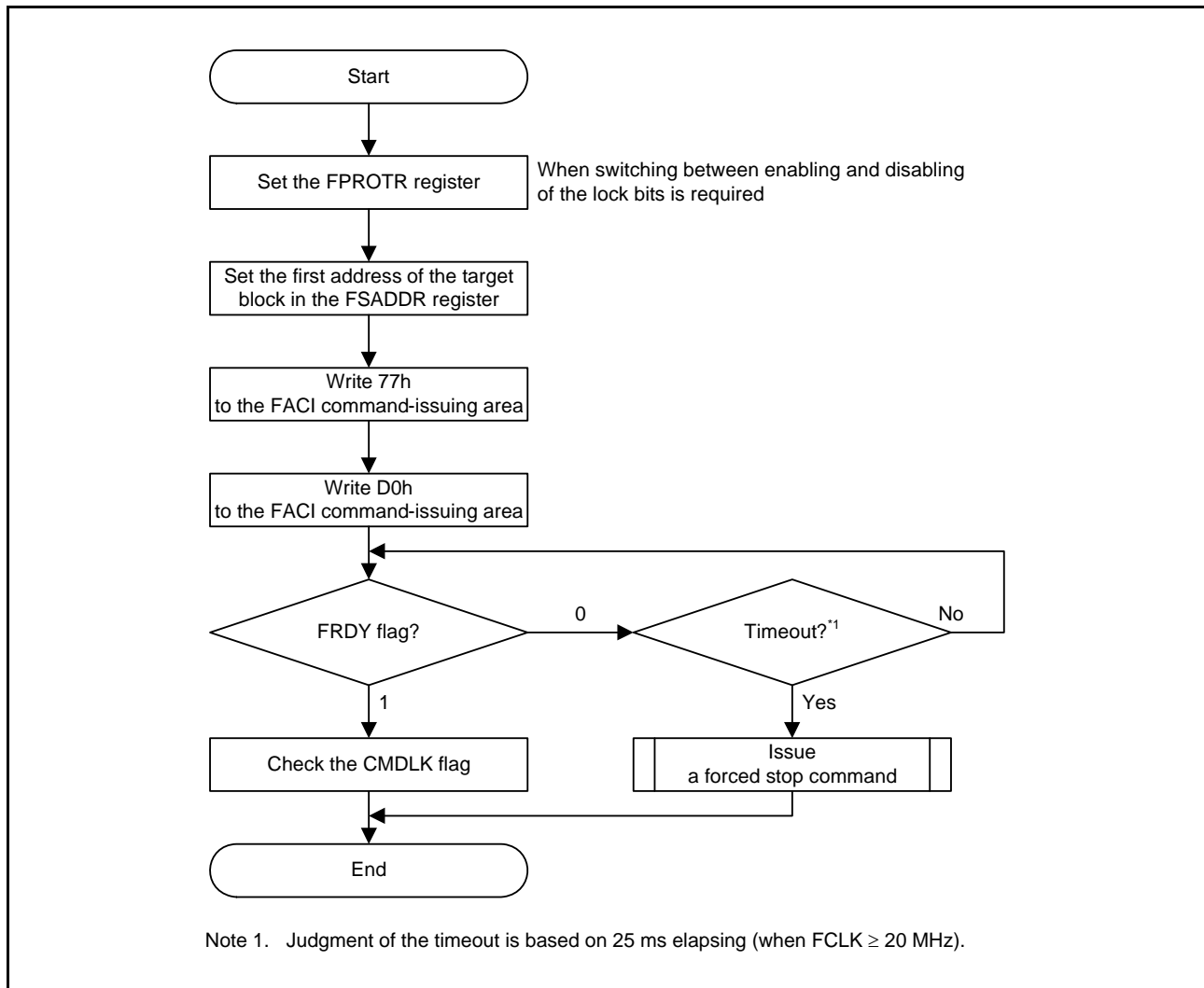


Figure 6.20 Usage of the Lock-Bit Programming Command

6.3.17 Lock-Bit Read Command

To read a lock bit, use the lock-bit read command. Before issuing a lock-bit read command, set the first address of the target block in the FSADDR register.

Writing 71h and D0h to the FCI command-issuing area starts processing of a lock-bit read command.

Completion of command processing can be confirmed with the FSTATR.FRDY flag. After command processing is completed, the result of reading the lock bit is stored in the FLKSTAT.FLOCKST flag.

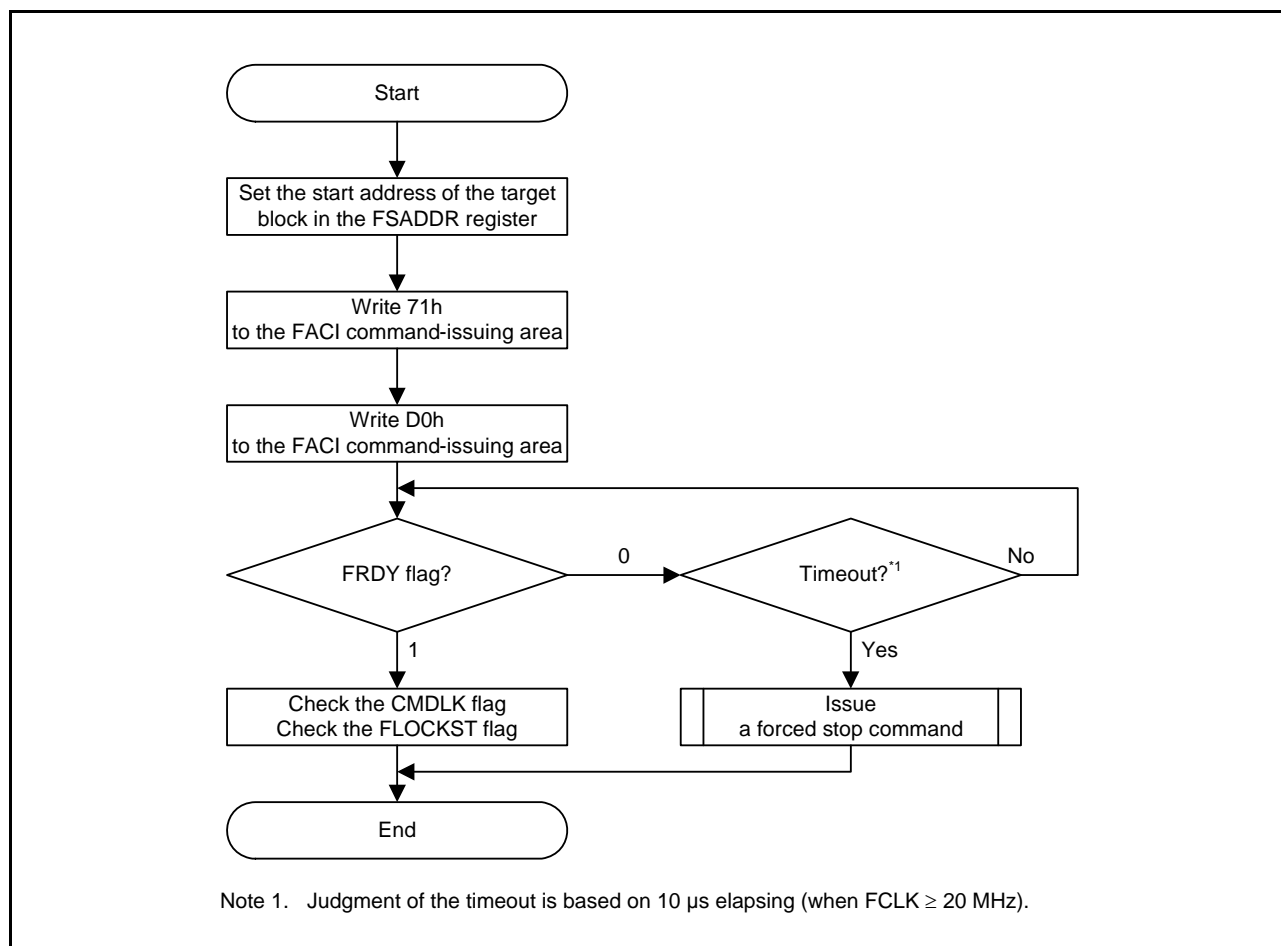


Figure 6.21 Usage of the Lock-Bit Read Command

7. Safety Function

7.1 Software Protection

Software protection disables programming and erasure for the code flash memory through the settings of control registers and lock bit settings in the user area. If an attempt is made to issue an FACI command against software protection, the flash sequencer enters the command-locked state.

7.1.1 Protection through FWEPROR

Unless the FWEPROR.FLWE[1:0] bits are set to 01b, programming cannot proceed in any mode.

7.1.2 Protection through FENTRYR

When the FENTRYR register is set to 0000h, the flash sequencer enters read mode. In read mode, FACI commands cannot be accepted. If an attempt is made to issue an FACI command in read mode, the flash sequencer enters the command-locked state.

7.1.3 Protection through Lock Bit

Each block in the user area includes a lock bit. When the FPROTR.FPROTCN bit is 0, blocks whose lock bit is set to 0 are prohibited from being programmed/erased. To program or erase blocks whose lock bit is set to 0, set the FPROTR.FPROTCN bit to 1. When the lock bit protection is violated and a code flash memory programming, block erase or lock-bit programming command is issued, the flash sequencer enters the command-locked state.

7.2 Error Protection

Error protection detects the issuing of illegal FACI commands, illegal access, and flash sequencer malfunction. FACI command acceptance is disabled (command-locked state) in response to the detection of these errors. The flash memory cannot be programmed or erased while the flash sequencer is in the command-locked state. For release from the command-locked state, issue a status clear or forced stop command while the CFAE and DFAE flags in the FASTAT register are 0. The status clear command can only be used while the FSTATR.FR DY flag is 1. The forced stop command can be used regardless of the value of the FSTATR.FR DY flag. While the FAEINT.CMDLKIE bit is 1, a flash access error (FIFERR) interrupt is generated if the flash sequencer enters the command-locked state (the FASTAT.CMDLK flag is set to 1).

If the flash sequencer enters the command-locked state in response to a command other than the P/E suspend command during programming or erasure processing, the flash sequencer continues the processing for programming or erasure. In this state, the P/E suspend command cannot be used to suspend the processing for programming or erasure. If a command is issued in the command-locked state, the FASTAT.ILGLERR flag becomes 1 and the other bits retain the values set due to previous error detection.

Table 7.1 shows error protection types and status bit values after error detection.

Table 7.1 Error Protection Type

Error Type	Description	ILGLERR	ERSERR	PRGERR	FCUERR	FLWEERR	CFGDTCT	TBLDTCT	FRDTCT	CFAE	DFAE
FENTRYR setting error	The FENTRYR setting is other than 0001h and 0080h.	1	0	0	0	0	0	0	0	0	0
	The FENTRYR setting at suspension disagrees with that at resumption.	1	0	0	0	0	0	0	0	0	0
Illegal command error	An undefined code is written in the first access of an FACI command.	1	0	0	0	0	0	0	0	0	0
	The value specified in the last access of the multiple-access FACI command is not D0h.	1	0	0	0	0	0	0	0	0	0
	The value (N) specified in the second write access of an FACI command in the programming or configuration setting command is wrong.	1	0	0	0	0	0	0	0	0	0
	A blank check command has been issued with inconsistent FBCCNT.BCDIR bit, FSADDR register, and FEADDR register settings (see section 4.6, FACI Command End Address Register (FEADDR)).	1	0	0	0	0	0	0	0	0	0
	An FACI command not acceptable in each mode has been issued (see Table 6.3).	1	0	0	0	0	0	0	0	0	0
	An FACI command has been issued when command acceptance conditions are not satisfied (see Table 6.4).	1	0/1	0/1	0/1	0/1	0/1	0/1	0/1	0/1	0/1
Erasure error	An error occurs during erasure.	0	1	0	0	0	0	0	0	0	0
	A block erase command has been issued against lock bit protection.	0	1	0	0	0	0	0	0	0	0
Programming error	An error occurs during programming.	0	0	1	0	0	0	0	0	0	0
	A programming or lock-bit programming command has been issued against lock bit protection.	0	0	1	0	0	0	0	0	0	0
FCU error	An error occurs during CPU processing in FCU.	0	0	0	1	0	0	0	0	0	0
FCURAM ECC error	A 2-bit error has been detected when FCURAM is read.	0	0	0	0	0	0	0	1	0	0
Code flash access violation	An FACI command has been issued to the reserved portion of the user area in code flash memory P/E mode (see section 4.2, Flash Access Status Register (FASTAT)).	1	0	0	0	0	0	0	0	1	0
Data flash access violation	An FACI command has been issued to the reserved portion of the data area in data flash memory P/E mode (see section 4.2, Flash Access Status Register (FASTAT)).	1	0	0	0	0	0	0	0	0	1
	A configuration set command has been issued to the reserved area (see section 4.2, Flash Access Status Register (FASTAT)).	1	0	0	0	0	0	0	0	0	1
Others	The FACI command-issuing area has been accessed in read mode.	1	0	0	0	0	0	0	0	0	0
	The FACI command-issuing area has been read in code flash memory P/E mode or data flash memory P/E mode.	1	0	0	0	0	0	0	0	0	0
Flash write erase protection error	A flash memory write protection error has been detected by the setting of the FWEPROR register* ¹ during command processing by the flash sequencer.	0	0/1	0/1	0	1	0	0	0	0	0
Configuration set ECC error	A 2-bit error has been detected when the configuration setting value is read.	0	0	0	0	0	1	0	0	0	0
Programming parameter ECC error	A 2-bit error has been detected when the overwrite parameter table is read.	0	0	0	0	0	0	1	0	0	0

Note 1. For details on the FWEPROR register, see section 4.1, Flash P/E Protect Register (FWEPROR).

7.3 Boot Program Protection

7.3.1 User Boot Protection

The user boot area can only be overwritten in programming mode (boot mode (for the SCI or USB interface)). Since this area is usually write-protected in normal operating mode and user boot mode, it can be used for the safe storage of programs such as a boot program.

8. Usage Notes

(1) Reading areas where programming or erasure was interrupted

When programming or erasure of an area of flash memory is interrupted, the data stored in the area become undefined. To avoid undefined data that are read out becoming the source of faulty operation, take care not to fetch instructions or read data from areas where programming or erasure was interrupted.

(2) Prohibition of additional writing

Writing to a given area twice is not possible. If you want to overwrite data in an area of flash memory after writing to the area has been completed, erase the area first.

(3) Resets during programming and erasure

In the case of a reset due to the signal on the RES# pin during programming and erasure, wait for at least t_{RESWF} (see the User's Manual: Hardware for details) once the operating voltage is within the range stipulated in the electrical characteristics after assertion of the reset signal before releasing the device from the reset state.

(4) Allocation of vectors for interrupts and other exceptions during programming and erasure

Generation of an interrupt or other exception during programming or erasure may lead to fetching of the vector from the code flash memory. If this does not satisfy the conditions for using background operation, set the address for vector fetching to an address that is not in the code flash memory.

(5) Abnormal termination of programming and erasure

Even if programming/erasure ends abnormally due to the generation of a reset by the RES# pin, the programming/erasure state of the flash memory with undefined data cannot be verified or checked. For the area where programming/erasure ends abnormally, the blank check function cannot judge whether the area is erased successfully or not. Erase the area again to prove that the corresponding area is completely erased before using.

If programming and erasure of code flash memory are not completed normally, the lock bit for the target area may be enabled (locked). In such cases, erase the block to erase the lock bit while the lock bit is in the disabled state (the area is not locked).

(6) Items prohibited during programming and erasure

Do not perform the following operations during programming and erasure.

- Have the operating voltage from the power supply go beyond the allowed range.
- Change the frequency of the PCLK/FCLK.

9. Electrical Characteristics

9.1 AC Characteristics

Conditions: $V_{CC} = AVCC0 = AVCC1 = V_{CC_USB} = V_{BATT} = 2.7$ to 3.6 V, $2.7 \leq V_{REFH0} \leq AVCC0$,
 $V_{CC_USBA} = AVCC_USBA = 3.0$ to 3.6 V,
 $V_{SS} = AVSS0 = AVSS1 = V_{REFL0} = V_{SS_USB} = V_{SS1_USBA} = V_{SS2_USBA} = PV_{SS_USBA} = AV_{SS_USBA} = 0$ V,
 $T_a = T_{opr}$

Item	Min.	Typ.	Max.	Unit	Conditions
FCURAM data transfer time	—	220	—	μ s	FCLK = 60 MHz and the FRAMTRAN bit in the FCURAME register is 0
	—	110	—	μ s	FCLK = 60 MHz and the FRAMTRAN bit in the FCURAME register is 1
FACI command setup time	—	—	100	μ s	FCLK \geq 20 MHz
FACI command processing time	—	—	0	$t_{F_{cyc}}$	For other than programming of code flash memory
	—	—	90	$t_{F_{cyc}}$	For programming of code flash memory
Forced stop command	—	—	20	μ s	$20\text{MHz} \leq \text{FCLK} \leq 60\text{MHz}$
	—	—	32	μ s	FCLK = 4MHz

Note: $t_{F_{cyc}}$: PCLKB/FCLK cycle

REVISION HISTORY	RX64M Group Flash Memory User's Manual: Hardware Interface
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Rev.	Date	Description	
		Page	Summary
0.90	May 30, 2014	—	First edition, issued
1.00	Jul 31, 2014	6. FACI Commands	
		8	Table 3.1 Information on the Hardware Interface Area, changed
		32	Table 6.1 List of FACI Commands, changed
		55	6.3.15 Configuration Set Command, changed
		56	Table 6.5 Address Used by Configuration Set Command, changed
		60	Table 7.1 Error Protection Type, changed
1.10	Nov 05, 2014	—	RX71M group, added
		All	Terms unified: RX64M User's Manual: Hardware or RX71M User's Manual: Hardware → User's Manual: Hardware
		1. Features	
		6	Body text changed
		2. Module Configuration	
		7	Body text changed
		4. Registers	
		10	4.1 Flash P/E Protect Register (FWEPROR), changed
		11	4.2 Flash Access Status Register (FASTAT), changed
		13	4.3 Flash Access Error Interrupt Enable Register (FAEINT)
		15	4.5 FACI Command Start Address Register (FSADDR), changed
		16	4.6 FACI Command End Address Register (FEADDR), changed
		17	4.7 FCURAM Enable Register (FCURAME), changed
		22	4.9 Flash P/E Mode Entry Register (FENTRYR), changed
		23	4.10 Flash Protection Register (FPROTR), changed
		24	4.11 Flash Sequencer Set-Up Initialization Register (FSUINTR), changed
		27	4.14 Flash P/E Status Register (FPESTAT), changed
		30	4.19 Flash Sequencer Processing Clock Notification Register (FPCKAR), changed
		6. FACI Commands	
		32	Table 6.1 List of FACI Commands, changed
		33	6.2 Relationship between the Flash Sequencer State and FACI Commands, changed
		35	Figure 6.1 Overview of Command Usage in Code Flash Memory P/E Mode (for products in which BGO is possible), changed
		36	Figure 6.2 Overview of Command Usage in Code Flash Memory P/E Mode (for products in which BGO is not possible), changed
		37	Figure 6.3 Overview of Command Usage in Data Flash Memory P/E Mode, changed
		40	Figure 6.7 Procedure for Transition to Read Mode, changed
		44	Figure 6.9 Usage of the Programming Command, changed
		46	6.3.10 P/E Suspend Command, changed
		48	Figure 6.12 Suspension during Programming, changed
		54	Figure 6.18 Usage of the Blank Check Command, changed
		55, 56	6.3.15 Configuration Set Command, changed Table 6.5 Address Used by Configuration Set Command, changed
		7. Safety Function	
		59	7.1.3 Protection through Lock Bit, changed
		60	Table 7.1 Error Protection Type, changed
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62	(3) Resets during programming and erasure, changed		

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